

### Li-ion battery monitoring and balancing IC

















### **Features**

- Voltage monitoring of up to 9 battery cells connected in series
- Hot plugging support
- Dedicated 16-bit high precision delta-sigma ADC for each cell with selectable measurement mode
- High-accuracy measurement with typical ±0.2 mV initial accuracy at ambient temperature with a typical lifetime adder of 1 LSB after 10 years of usage
- Integrated stress sensor with digital compensation algorithm and temperature-compensated measurements
- Secondary ADC with identical averaging filter characteristics as advanced end-to-end safety mechanism
- Five temperature measurement channels for external NTC elements
- Two internal temperature sensors
- Integrated balancing switch allows up to 200 mA balancing current
- Differential robust serial 2 Mbit/s communication interface with up to 38 devices
- Additional four GPIO pins to e.g. connect an external EEPROM and PWM driver
- Internal round robin cycle routine triggers majority of diagnostics mechanisms
  - Automatic balancing overcurrent and undercurrent detection
  - Automatic open load and open wire detection
  - Automatic NTC measurement unit monitoring
- End-to-end CRC secured iso UART/UART communication
- Wake from bus capability (EMM)
- ISO 26262 Safety Element out of Context for safety requirements up to ASIL D
- Green Product (RoHS compliant)

# **Potential applications**

Multi-cell battery monitoring and balancing system IC designed for Li-ion battery packs used in hybrid electric vehicles (HEV), plug-in hybrid electric vehicles (PHEV), battery electric vehicles (BEV) as well as in 12 V/48 V Li-ion batteries and energy storage systems (ESS).

### **Product validation**

Qualified for automotive applications. Product validation according to AEC-Q100.



### Li-ion battery monitoring and balancing IC



**Description** 

# **Description**

The device is a IC for lithium-ion battery cell management. The main function is to measure all cell voltages in parallel with high precision and accuracy as well as temperatures. Additionally, the device is able to individually and parallelly balance all cell voltages. The device offers a UART interface and an isolated daisy chain interface called iso UART for communication with the host controller. The small package design and robust technology enables a lean design and a ultra low bill of materials.

Туре	Package	Marking
TLE9009DQU	PG-TQFP-48	TLE9009DQU

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### 1 Block diagram

# 1 Block diagram

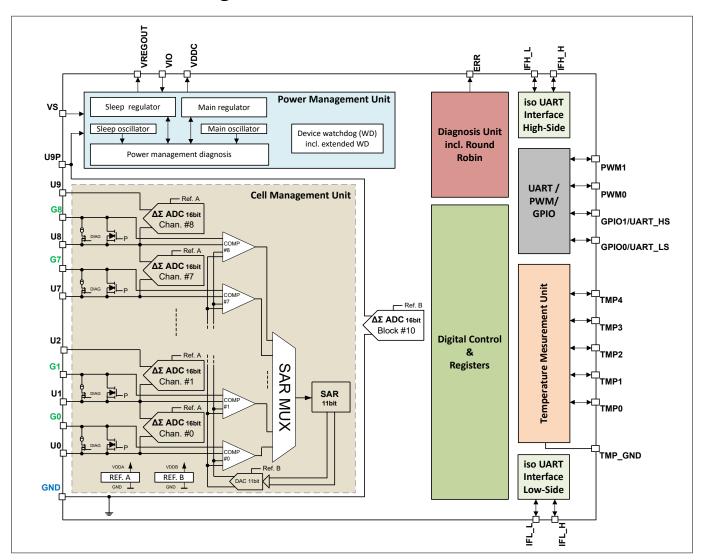


Figure 1 Block diagram



### 2 Pin configuration

#### **Pin configuration** 2

#### Pin assignment 2.1

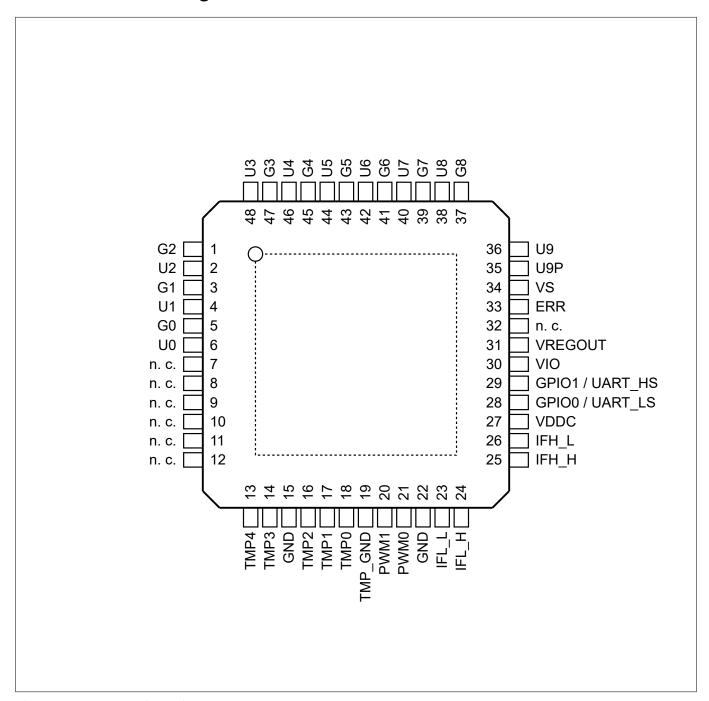


Figure 2 Pin assignment

#### Pin definitions and functions 2.2

Pin	Symbol	Pin type	Function
1	G2	A_I / O	Cell-balancing channel 2.
2	U2	A_I	Cell voltage measurement channel 2, negative terminal (positive terminal of cell 1).

# Li-ion battery monitoring and balancing IC



# 2 Pin configuration

Pin	Symbol	Pin type	Function
3	G1	A_I / O	Cell-balancing channel 1.
4	U1	A_I	Cell voltage measurement channel 1, negative terminal (positive terminal of cell 0).
5	G0	A_I / O	Cell-balancing channel 0.
6	U0	A_I	Cell voltage measurement channel 0, negative terminal (same potential as local GND).
7	n. c.		Not connected. Connect to U0 in application.
8	n. c.		Not connected. Connect to U0 in application.
9	n. c.		Not connected. Connect to U0 in application.
10	n. c.		Not connected. Connect to U0 in application.
11	n. c.		Not connected. Connect to U0 in application.
12	n. c.		Not connected. Connect to U0 in application.
13	TMP4	Ю	Temperature sensor 4. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ . If TMP4 is disabled, the pin can be used as 0 to 2 V auxiliary ADC miscellaneous pin.
14	TMP3	Ю	Temperature sensor 3. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ . If TMP3 is disabled, the pin can be used as 0 to 2 V auxiliary ADC miscellaneous pin.
15	GND	GND	Local GND of CSC (cell supervision circuit) device
16	TMP2	Ю	Temperature sensor 2. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ . If TMP2 is disabled, the pin can be used as 0 to 2 V auxiliary ADC miscellaneous pin.
17	TMP1	Ю	Temperature sensor 1. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ . If TMP1 is disabled, the pin can be used as 0 to 2 V auxiliary ADC miscellaneous pin.
18	ТМР0	Ю	Temperature sensor 0. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ . If TMP0 is disabled, the pin can be used as 0 to 2 V auxiliary ADC miscellaneous pin.
19	TMP_GN D	Ю	Temperature sensor reference. This pin can be connected to local GND.
20	PWM1	Ю	PWM output channel 1. This pin also has a general purpose input/output function. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ .
21	PWM0	Ю	PWM output channel 0. This pin also has a general purpose input/output function. If not used connect pin to GND via a pull-down resistor > 10 k $\Omega$ .
22	GND	GND	Local GND of CSC device (cell supervision circuit).
23	IFL_L	D_I / O	Lower isolated UART (iso UART) L pin.
24	IFL_H	D_I / O	Lower isolated UART (iso UART) H pin.
25	IFH_H	D_I / O	Upper isolated UART (iso UART) H pin.
26	IFH_L	D_I / O	Upper isolated UART (iso UART) L pin.
27	VDDC	Supply	Buffer capacitor pin for internal iso UART supply.

# Li-ion battery monitoring and balancing IC



# 2 Pin configuration

Pin	Symbol	Pin type	Function
28	GPIO0 / UART_LS	D_I / O	General-purpose input/output channel 0. This pin also has the function of UART_LS. If not used connect pin to GND.
29	GPIO1 / UART_HS	D_I / O	General-purpose input/output channel 1. This pin also has the function of UART_HS. If not used connect pin to GND.
30	VIO	S	Supply for GPIO interface.
31	VREGOU T	S	Output pin for the internal regulator.
32	n. c.	n. c.	Not connected. Connect to GND in application.
33	ERR	HV_D_O	Error output to microcontroller; open drain PMOS connected to VS. If not used, leave unconnected.
34	VS	S	Supply pin of internal regulator $V_{VREGOUT}$ .
35	U9P	S	Positive supply pin. Connect to positive terminal of topmost cell in block. Input for the sleep regulator.
36	U9	A_I	Cell voltage measurement channel 8, positive terminal (most upper cell in the block).
37	G8	A_I / O	Cell-balancing channel 8.
38	U8	A_I	Cell voltage measurement channel 8, negative terminal (positive terminal of cell 7).
39	G7	A_I / O	Cell-balancing channel 7.
40	U7	A_I	Cell voltage measurement channel 7, negative terminal (positive terminal of cell 6).
41	G6	A_I / O	Cell-balancing channel 6.
42	U6	A_I	Cell voltage measurement channel 6, negative terminal (positive terminal of cell 5).
43	G5	A_I / O	Cell-balancing channel 5.
44	U5	A_I	Cell voltage measurement channel 5, negative terminal (positive terminal of cell 4).
45	G4	A_I / O	Cell-balancing channel 4.
46	U4	A_I	Cell voltage measurement channel 4, negative terminal (positive terminal of cell 3).
47	G3	A_I / O	Cell-balancing channel 3.
48	U3	A_I	Cell voltage measurement channel 3 negative terminal (positive terminal of cell 2).
49	Exposed Pad	GNDA	Cooling tab. Connect to GND in the application.

Pin types: A = analog, D = digital, HV = high-voltage, I = input, O = output, I/O = bidirectional, P = power, S = supply

### Li-ion battery monitoring and balancing IC



### 3 General product characteristics

# **3** General product characteristics

Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the electrical characteristics table.

This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

# 3.1 Absolute maximum ratings

### Table 1 Absolute maximum ratings

 $T_j$  = -40°C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	ool Values			Unit	Note or condition	P-	
		Min.	Тур.	Max.			Number	
Voltages		•	'	•	1		-	
Supply voltage VS	V <sub>VS_max</sub>	-0.3	_	75	V	-	PRQ-486	
Supply voltage VS relative	V <sub>VS_rel_max</sub>	V <sub>VREG</sub> OUT - 0.3	_	_	V	-	PRQ-489	
Transient high voltage	V <sub>transient_hi</sub>	75	_	90	V	Maximum transient duration 60 sec. Valid for following pins vs. GND: VS, U9P, U9, Gn, Un (0 ≤ n ≤ 8)	PRQ-1862	
Supply voltage U9P	V <sub>U9P_max</sub>	-0.3	-	75	V	-	PRQ-1861	
Supply voltage VIO	V <sub>VIO_max</sub>	-0.3	_	5.5	V	-	PRQ-488	
Regulator output VREGOUT	V <sub>VREGOUT</sub>	-0.3	_	3.6	V	-	PRQ-490	
Regulator output VDDC	V <sub>VDDC_max</sub>	-0.3	-	3.6	V	Assuming I <sub>VDDC</sub> ≤ 1 mA continuous current	PRQ-491	
Cell sense input voltage absolute Un	V <sub>Un_max</sub>	-0.3	_	75	V	0 ≤ n ≤ 9	PRQ-1863	
Cell sense input voltages relative Un	V <sub>Un_rel_max</sub>	V <sub>Un-1</sub> - X	-	V <sub>Un-1</sub> + 9	V	<ol> <li>1. 1≤n≤9</li> <li>2. x=-0.0016 × T<sub>j</sub> + 0.54</li> <li>3. Typical clamping voltage</li> <li>4. Maximum allowed current into/out of the pin: 40 mA</li> <li>5. For 7.5 V &lt; V<sub>Un</sub> &lt; 9 V: Current flowing into the pin is below 10 mA</li> </ol>	PRQ-1864	

### Li-ion battery monitoring and balancing IC



# **3 General product characteristics**

# Table 1 (continued) Absolute maximum ratings

 $T_j$  = -40°C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Cell balancing pin absolute Gn	V <sub>Gn_max</sub>	-0.3	-	75	V	0 ≤ n ≤ 8	PRQ-1866
Cell balancing pins relative Gn	V <sub>Gn_rel_max</sub>	V <sub>Un</sub> - 0.3	_	V <sub>Un+1</sub> + 0.3	V	0 ≤ n ≤ 8	PRQ-1867
General purpose I/O voltages absolute GPIOq	$V_{GPIOq\_max}$	-0.3	-	5.5	V	0 ≤ q ≤ 1	PRQ-505
General purpose I/O voltages relative GPIOq	V <sub>GPIOq_rel_</sub> max	-0.3	-	V <sub>VIO</sub> + 0.3	V	0 ≤ q ≤ 1	PRQ-506
Open drain output pin absolute ERR	V <sub>ERR_max</sub>	-0.3	-	75	V	-	PRQ-510
Open drain output pin relative ERR	V <sub>ERR_rel_ma</sub>	-0.3	_	V <sub>VS</sub> + 0.3	V	-	PRQ-509
iso UART interface IFL_x	V <sub>IFL_L_max</sub> V <sub>IFL_H_max</sub>	-4.1	_	6.6	V	BCI test maximum 300 mA injected via twisted pair cable onto iso UART interface (maximum pin current 150 mA)	PRQ-493
iso UART interface IFH_x	V <sub>IFH_L_max</sub> V <sub>IFH_H_max</sub>	-4.1	_	6.6	V	BCI test maximum 300 mA injected via twisted pair cable onto iso UART interface (maximum pin current 150 mA)	PRQ-492
Temperature sensor input voltages absolute TMPz	V <sub>TMPz_max</sub>	-0.3	-	3.63	V	0 ≤ z ≤ 4	PRQ-863

### Li-ion battery monitoring and balancing IC



# **3 General product characteristics**

#### Table 1 (continued) Absolute maximum ratings

 $T_i$  = -40°C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Temperature sensor input voltages relative TMPz	V <sub>TMPz_rel_m</sub>	-0.3	-	V <sub>VREG</sub> out <sup>+</sup> 0.3	V	0 ≤ z ≤ 4	PRQ-864
Temperature sensor input voltage absolute TMP_GND	V <sub>TMP_GND_</sub> max	-0.3	-	2.75	V	_	PRQ-503
Temperature sensor input voltages relative TMP_GND	V <sub>TMP_GND_r</sub> el_max	-0.3	-	V <sub>VREG</sub> out <sup>+</sup> 0.3	V	-	PRQ-504
Pulse width modulation I/O voltages absolute PWMp	V <sub>PWMp_max</sub>	-0.3	-	5.5	V	0 ≤ p ≤ 1	PRQ-865
Pulse width modulation I/O voltages relative PWMp	V <sub>PWMp_rel_</sub>	-0.3	-	V <sub>VIO</sub> + 0.3	V	0 ≤ p ≤ 1	PRQ-866
Ground pin GND	$V_{GND}$	0	-	0	V	Absolute GND	PRQ-511
ESD robustne	ess						
ESD robustness 2 kV	V <sub>ESD_2kV_m</sub>	-2	_	2	kV	2) HBM; all pins	PRQ-514
ESD robustness 4 kV	V <sub>ESD_4kV_m</sub>	-4	-	4	kV	HBM; robustness versus GND for pins: VS, U9P, Un, Gn, TMPz, TMP_GND, IFH_x, IFL_x	PRQ-1865
ESD robustness CDM 500 V	V <sub>ESD_cdm_al</sub>	-500	-	500	V	3) CDM; all pins	PRQ-516
ESD robustness CDM 750 V	V <sub>ESD_Corner</sub> _max	-750	_	750	V	3) CDM; corner pins	PRQ-517

### Li-ion battery monitoring and balancing IC



### 3 General product characteristics

#### Table 1 (continued) Absolute maximum ratings

 $T_j$  = -40°C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Temperature	es						·
Junction temperature	T <sub>j_max</sub>	-40	_	150	°C	-	PRQ-512
Storage temperature	T <sub>stg_max</sub>	-55	_	150	°C	-	PRQ-513

<sup>1)</sup> Positive and negative transients with a maximum duration of 100 ns allowed between ± 8 V; This should simulate ESD events; however, during normal and steady-state condition voltage on these pins must stay inside the maximum ratings specified.

#### **Notes:**

- 1. Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- 2. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as outside normal operating range. Protection functions are not designed for continuous repetitive operation.

### 3.2 Functional range

### Table 2 Functional range

 $T_j$  = -40°C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	ol Values			Unit	Note or condition	P-
		Min.	Тур.	Max.	1		Number
Supply voltage VS	V <sub>VS_function</sub>	4.75	-	60	V	-	PRQ-518
Supply voltage U9P	V <sub>U9P_functio</sub>	4.75	_	45	V	_	PRQ-1868
Supply voltage VIO	V <sub>VIO_functio</sub>	3	_	5.5	V	-	PRQ-520
Cell sense input voltage Un	V <sub>Un_function</sub>	V <sub>Un-1</sub> - x	_	V <sub>Un-1</sub> + 7	V	1. $1 \le n \le 9$ 2. $x = -0.0016 \times T_j + 0.54$	PRQ-1869

<sup>2)</sup> ESD robustness, HBM according to ANSI/ESDA/JEDEC JS-001 (1.5 k $\Omega$ , 100 pF).

<sup>3)</sup> ESD robustness, Charged Device Model JESD22-C101.

### Li-ion battery monitoring and balancing IC



### 3 General product characteristics

### 3.3 Thermal resistance

### Table 3 Thermal resistance

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Junction to case	$R_{thJC}$	-	7	-	K/W	1)	PRQ-1921
Junction to ambient	$R_{thJA}$	-	32	_	K/W	1) 2)	PRQ-1922

<sup>1)</sup> Not subject to production test, specified by design.

<sup>2)</sup> Specified *R*thJA value is according to JEDEC JESD51-5,-7 at natural convection on FR4 2s2p board; The product (chip and package) was simulated on a 76.2 × 114.3 × 1.5 mm board with 2 inner copper layers (2 × 70 μm Cu, 2 × 35 μm Cu). The thermal via array under the exposed pad consists of 16 vias with a diameter of 0.3 mm and a plating thickness of 25 μm.

### Li-ion battery monitoring and balancing IC



### 4 Monitoring of internal oscillators

# 4 Monitoring of internal oscillators

The IC includes monitoring of two internal oscillators:

- **1.** Main oscillator operating at  $f_{\text{main\_osc}}$
- 2. Sleep oscillator operating at  $f_{\text{sleep\_osc}} \rightarrow$  in sleep mode only the sleep mode oscillator is active In normal mode both oscillators are active. The oscillators monitor each other for drift and stuck-at errors. As soon as the IC detects an error, it enters sleep mode. The oscillator error prevents reliable writing to any register and hence the IC does not set any error bit before entering sleep mode.

# 4.1 Electrical characteristics monitoring of internal oscillators

#### Table 4 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Oscillator							,
Main unit oscillator frequency	f <sub>main_osc</sub>	13.4 4	14	14.5 6	MHz	-	PRQ-564
Sleep unit oscillator frequency	f <sub>sleep_osc</sub>	90	100	110	kHz	-	PRQ-565



5 Power Management Unit (PMU)

# 5 Power Management Unit (PMU)

### 5.1 Functional description

The IC has an internal power supply unit connected to the pins VS, U9P and GND. It consumes energy from the monitored battery cells and generates the internal supply voltages for the IC as well as the output voltages  $V_{VDDC}$  and  $V_{VREGOUT}$ .

Note: The output pins VDDC and VREGOUT require a capacitance to ground as stated in the Application information/External components.

Note: No supply currents are drawn from Un pins.

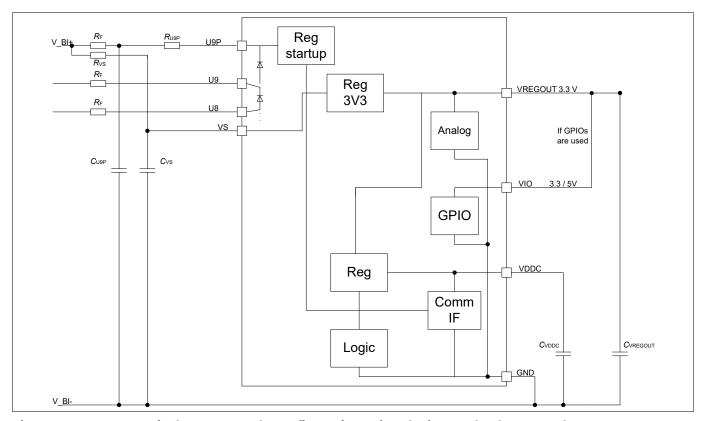


Figure 3 Typical power supply configuration using the internal voltage regulator

The IC has a sleep mode with reduced current consumption supplied via U9P and GND.

The IC can be put into sleep mode by setting the sleep mode bit. The sleep mode features a reduced current consumption,  $I_{U9P\_sleep}$ , supplied via U9P and GND.

To supply the communication interface, the device provides a regulated output voltage  $V_{\text{VDDC}}$  on pin VDDC.

If the voltage  $V_{VDDC}$  falls below the undervoltage threshold  $V_{VDDC\_th\_UV}$  for a longer time than  $t_{PS\_ERR\_deg}$ , then the IC enters sleep mode. The power supply error sleep bit in the general diagnostics register indicate a fault, which can be read after waking the IC.

The device provides a regulated output voltage  $V_{VREGOUT}$  with an output current  $I_{VREGOUT}$  on pin VREGOUT which can supply the GPIOs of the device or other loads.

The multi purpose supply incorporates an overcurrent protection. If the current  $I_{VREGOUT}$  exceeds  $I_{VREGOUT\_th\_OC}$  for a longer time than  $t_{PS\_ERR\_deg}$ , then it switches off the output voltage supply. The IC enters sleep mode after the deglitching time  $t_{PS\_ERR\_deg}$ . The power supply error sleep bit in the general diagnostics register indicates a fault, which can be read after waking up the IC.

### Li-ion battery monitoring and balancing IC



#### 5 Power Management Unit (PMU)

The voltage at the VIO pin sets the logic levels and supplies the GPIOs. The pin can be connected directly to the VREGOUT pin or to another desired voltage level using an external regulator.

If the voltage  $V_{\text{VIO}}$  falls below the undervoltage threshold  $V_{\text{VIO}\_\text{th}\_\text{UV}\_\text{fall}}$  for a longer time than  $t_{\text{PS}\_\text{ERR}\_\text{deg}}$ , then the IC sets the VIO undervoltage error bit in the general purpose input/output register. After  $V_{\text{VIO}}$  has exceeded the  $V_{\text{VIO}\_\text{th}\_\text{UV}\_\text{rise}}$  threshold for longer than  $t_{\text{PS}\_\text{ERR}\_\text{deg}}$ , the UV\_VIO bit can be cleared with a write command.

Note: If the GPIO.VIO\_UV bit is 0, the GPIO functionality is enabled and wake-up via GPIO is possible.

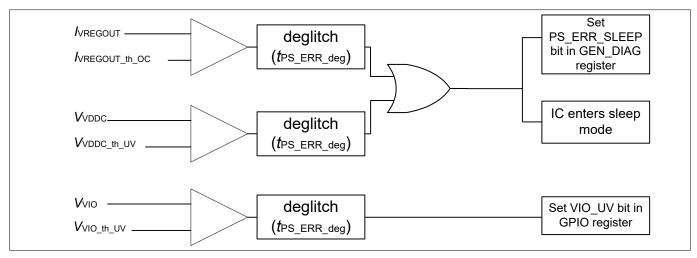


Figure 4 Power supply monitoring

The IC ensures wake-up and operation even if any single wire connected to a cell is open in case of failure (assumption: U9P and VS connected on PCB level). If an absolute maximum rating is violated due to an open wire, then performance degradation may occur.

# 5.2 Electrical characteristics power management unit (PMU)

#### Table 5 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values			Note or condition	P-
		Min.	Тур.	Max.			Number
Internal regu	ılators						·
VREGOUT internal regulator output voltage	V <sub>VREGOUT</sub>	3.3	3.45	3.6	V	-	PRQ-544
VDDC output voltage	$V_{\mathrm{VDDC}}$	2.42	2.5	2.63	V	-	PRQ-549

### Li-ion battery monitoring and balancing IC



# 5 Power Management Unit (PMU)

### Table 5 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Value	S	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Supply curre	nts						
Current consumption in 100 ms period - RT	/vs_100ms_c yc_RT	5.4	5.6	5.8	mA	<ol> <li>T<sub>j</sub> = 25°C</li> <li>Assumed cycle 100 ms period and 16-Bit mode (EN_ALL_ADC = 1)</li> <li>5% cell Voltage Measurement</li> <li>40% NTC current source activated</li> <li>5% diagnostics (Temperature and RR)</li> <li>7% communication</li> <li>43% idle</li> <li>Current to charge-up external interface components not included (see I<sub>VS_comm_ext</sub>)</li> </ol>	PRQ-563
U9P sleep mode current	I <sub>U9P_sleep</sub>	_	2.5	9.9	μА	<ol> <li>Typical value at T<sub>j</sub> = 25°C</li> <li>-40°C ≤ T<sub>j</sub> ≤ 85°C;</li> <li>Round robin in sleep mode deactivated</li> </ol>	PRQ-1870
U9P sleep mode current - room temperature	I <sub>U9P_sleep_R</sub>	-	2.5	3.5	μА	T <sub>j</sub> = 25°C	PRQ-1871
U9P idle current	I <sub>U9P_idle</sub>	-	2.5	10	μΑ	IC in idle mode	PRQ-1872
VS sleep mode leakage current	I <sub>VS_sleep</sub>	-1	_	1	μА	-40°C < T <sub>j</sub> < 85°C	PRQ-555
VS idle current	I <sub>VS_idle</sub>	_	4.9	6.5	mA	IC in idle mode	PRQ-557
VREGOUT current consumption multi purpose supply	/ <sub>VREGOUT</sub>	-	-	5	mA	No load on VIO	PRQ-1373

### Li-ion battery monitoring and balancing IC



# 5 Power Management Unit (PMU)

### Table 5 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	<b>;</b>	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
VIO current consumption during GPIO communicati on	I <sub>VIO_comm</sub>	-	-	5	mA	No load on VREGOUT	PRQ-558
VS current consumption during PCVM, SCVM and BVM measuremen t	I <sub>VS_meas</sub>	-	22.5	24	mA	<ol> <li>PCVM (EN_ALL_ADC = 1)</li> <li>SCVM</li> <li>BVM</li> <li>VIO connected to VREGOUT</li> <li>Including idle consumption I<sub>VS_idle</sub></li> </ol>	PRQ-559
VS current consumption during round robin scheme running	I <sub>VS_RR</sub>	-	9.0	11	mA	<ol> <li>Average current consumption during round robin</li> <li>VIO connected to VREGOUT</li> <li>Including idle consumption I<sub>VS_idle</sub></li> <li>NR_TEMP_SENSE ≥ 2, EN_ALL_ADC = 1, CVM_DEL = 0x01</li> </ol>	PRQ-560
VS current consumption during communicati on	I <sub>VS_comm</sub>	-	I <sub>VS_idl</sub> e_typ + 0.9	I <sub>VS_idl</sub> e_max + 1.2	mA	<ol> <li>GPIO communication.</li> <li>Current to charge external interface components not included.</li> </ol>	PRQ-561
VS current consumption during iso UART communicati on including external interface components	I <sub>VS_comm_is</sub>	-	-	/ <sub>VS_co</sub> mm + 7.6	mA	<ol> <li>C<sub>ser</sub> = 1 nF</li> <li>BR<sub>iso_U</sub> = 2 Mbit/s</li> <li>R<sub>ser</sub> = 39 Ω</li> <li>C<sub>isoUART_F</sub> = 220 pF</li> <li>Valid for one iso UART interface in TX mode</li> </ol>	PRQ-562
Protection an	d Detection	· !		•			
VREGOUT overcurrent threshold	/ <sub>VREGOUT_th</sub>	31	40	60	mA	Tested during idle mode	PRQ-545
VIO undervoltage threshold falling	V <sub>VIO_th_UV_f</sub>	2.2	-	2.76	V	-	PRQ-546

### Li-ion battery monitoring and balancing IC



# 5 Power Management Unit (PMU)

### Table 5 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	;	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
VIO undervoltage threshold rising	V <sub>VIO_th_UV_r</sub> ise	2.24	_	2.9	V	-	PRQ-547
VIO undervoltage threshold hysteresis	V <sub>VIO_th_UV_</sub> hys	40	100	160	mV	-	PRQ-548
VDDC undervoltage threshold	V <sub>VDDC_th_U</sub> v	2.15	_	2.42	V	_	PRQ-550
VDDC undervoltage threshold hysteresis	V <sub>VDDC_th_U</sub> v_hys	80	100	140	mV	_	PRQ-551
Power supply error detection deglitch time	t <sub>PS_ERR_deg</sub>	8	15	24	μs	1)	PRQ-552

<sup>1)</sup> Not subject to production test; verified by design or characterization.

### Li-ion battery monitoring and balancing IC



6 Watchdog and wake-up function (WD)

# 6 Watchdog and wake-up function (WD)

### **6.1** Functional description

The following events trigger a wake-up:

- A wake-up pattern received via the iso UART or UART interfaces. The signal alternates with the frequency  $f_{\text{WAKEUP}}$ . After  $n_{\text{WAKE\_det}}$  signal periods received by the IC, it performs a wake-up. The IC completes the wake-up process within  $t_{\text{wake}}$ . After that the IC forwards the same wake-up signal for  $n_{\text{WAKEUP}}$  periods. The IC forwards a wake-up signal received via UART to the iso UART interface, a wake-up signal received via iso UART to the adjacent iso UART interface.
- **2.** A round robin sleep timeout.
- **3.** An EMM signal recognized as wake-up signal.

The IC generates the wake-up pattern on:

- IFL, if the IC received a valid wake-up pattern on interface IFH.
  - (1) indicates the source of wake-up, (2) indicates the propagation on IFL\_x
- IFH, if the IC received a valid wake-up pattern on interface IFL.
  - (3) indicates the source of wake-up, (4) indicates the propagation on IFH\_x
- IFL, if the IC received a valid wake-up pattern on interface GPIO1/UART\_HS.
  - (5) indicates the source of wake-up, (6) indicates the propagation on IFL\_x
- IFH, if the IC received a valid wake-up pattern on interface GPIO0/UART\_LS.
  - (7) indicates the source of wake-up, (8) indicates the propagation on IFH\_x



#### 6 Watchdog and wake-up function (WD)

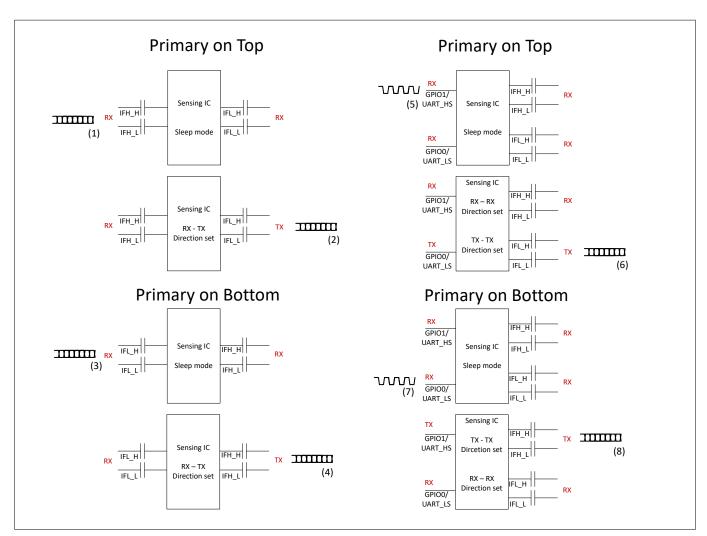


Figure 5 Wake-up signal propagation

The device configures the communication interface automatically after wake-up.

The device configures the iso UART interface of the wake-up signal received as RX during idle mode (no communication) until the next wake-up. The device configures the other iso UART interface as TX in idle mode until the next wake-up.

The IC has a 7-bit watchdog counter which is counting downwards. The watchdog counter must be serviced via an UART or iso UART command before it reaches 0. Otherwise the device enters sleep mode. The watchdog counter can be set to maximum  $t_{\rm WD\ max}$  with a resolution of  $t_{\rm WD\ LSB}$ , via the watchdog counter register.

Note: After the IC wake-up, the watchdog counter is set to its maximum value  $t_{WD\ max}$ 

If a longer counter interval is needed, the IC can be put into an extended watchdog mode by setting the operation mode register. In this mode the maximum time until the watchdog counter expires is defined by  $t_{\rm WD~EXT~max}$  with a resolution of  $t_{\rm WD~EXT~LSB}$ . When the counter expires, the device enters sleep mode.

The device provides a free-running 9-bit main counter which is counting upwards and can be checked via the communication interface reading the watchdog counter register.

The maximum length is  $t_{Count\_max}$  with a resolution of  $t_{Count\_LSB}$ . The precisely timed reading of the main counter gives an indication of the main oscillator speed.

If bitfield RR\_CONFIG.RR\_SYNC is set, then a WDOG\_CNT write command resets the main counter. This prepares for a broadcast read of all main counters.

After the device wakes up on a standard wake-up signal the device's node ID is set to 0 by default. In this state, the device does not forward any communication. A node ID other than 0 must be set in the address (ID) bits of configuration register before the watchdog timer expires. Only then the device forwards communication.

Note: If an EMM signal is received, the device forwards it even though the device is not enumerated.

### Li-ion battery monitoring and balancing IC



6 Watchdog and wake-up function (WD)

# 6.2 Electrical characteristics watchdog and wake-up function (WD)

# Table 6 Electrical characteristics

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	s	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Wake-up fund	ction						
WD wake-up signal frequency	$f_{WAKEUP}$	48	50	1040	kHz	_	PRQ-572
WD device wake-up time	t <sub>WAKE</sub>	200	370	500	μs	48 kHz wake-up frequency. From the first falling edge of the input pattern to the first edge of the propagated wake-up sequence.	PRQ-573
WD wake-up - number of detected periods	n <sub>WAKE_det</sub>	4	_	8	period s	_	PRQ-574
WD wake-up propagation - length in periods	n <sub>WAKE</sub>	8	_	8	period s	_	PRQ-575
Watchdog co	unter						
WD interval step	t <sub>WD_LSB</sub>	14.5	16	17.8	ms	1) EXT_WD = 0	PRQ-576
WD maximum interval	t <sub>WD_max</sub>	1.8	2.03	2.3	S	1) EXT_WD = 0	PRQ-578
WD interval step - extended	t <sub>WD_EXT_LSB</sub>	13.5	15.0 7	17	min	1) EXT_WD = 1	PRQ-577
WD maximum interval - extended	t <sub>WD_EXT_ma</sub>	28.9	31.9	35.5	h	1) EXT_WD = 1	PRQ-579
Main counter	•						
WD main counter interval step	t <sub>Count_LSB</sub>	281	292. 57	305	μs	1)	PRQ-580
WD main counter maximum interval	t <sub>Count_max</sub>	144. 03	149. 8	156. 03	ms	1)	PRQ-581

# Li-ion battery monitoring and balancing IC



6 Watchdog and wake-up function (WD)

1) Not subject to production test; verified by design or characterization.

### Li-ion battery monitoring and balancing IC



7 Measurement control (MC)

# 7 Measurement control (MC)

### 7.1 Functional description

The various voltage measuring modules on the IC follow these rules:

- All voltage measurements (PCVM, SCVM, BVM, BAVM, AVM) can be manually triggered by a communication command.
- A triggered measurement sets a lock bit which inhibits a measurement triggered by a cyclical task. The device clears the lock bit after completion of the measurement.
- BVM, PCVM and SCVM can be triggered simultaneously.
- Bipolar auxiliary voltage measurement (BAVM), PCVM and SCVM can be triggered simultaneously.

The IC provides two independent reference voltages which are used with the SD-ADC blocks.

- **1.** PCVM uses reference A.
- **2.** BVM, AVM, and SCVM use reference B.

The resolution of the various voltage measurements is  $V_{x\_LSB}$  and is defined by the LSB of the digital conversion. x=PCVM; SCVM; AVM; BVM

The measurement time  $t_{\rm VM}$  of the PCVM, SCVM and BVM is configurable in the measurement control register. PCVM/SCVM uses the cell voltage measurement mode bits, while BVM uses the block/auxiliary bits.

Table 7 Voltage measurement modes

CVM_Mode/ BVM_Mode [2:0]	PCVM/BVM resolution	SCVM resolution [bit]	t <sub>VM</sub> [ms]
	[bit]		
111	14	11	$t_{VM\_LR}$
110	16	11	4.68
101	15	11	2.34
100	14	11	1.17
011	13	11	0.59
010	12	11	0.29
001	11	11	0.15
000	10	11	0.07

Note: The resolution of AVM is 10 bit. The resolution of SCVM is 11 bit.  $t_{vm}$  of SCVM is adjusted to CVM\_MODE configuration.

Setting the start bit of a measurement in the measurement control register initiates a voltage measurement. The result of the measurement is the average of the cell voltage over the measurement time and is available in the RESULT register.

The resolution of the measured value (in bit) can be configured using the measurement control register.

On completion of a measurement the device clears the corresponding start bit. For manually triggered measurements (PCVM, SCVM, BVM), the result registers are set to 0 during measurement time  $t_{\rm VM}$  and measurement delay time  $t_{\rm VM}$  DEL, except in long-running mode.

In long-running mode, the result register is updated after the end of the measurement.

The result registers of the voltage measurement keep the results irrespective of internal cyclic diagnostics checks.

The configurable delay time  $t_{\text{VM\_del}}$  delays the start of the cell voltage, block voltage and bipolar auxiliary voltage measurements (PCVM, SCVM, BVM and BAVM) with a resolution of  $t_{\text{VM\_del}}$  LSB.

The maximum delay time is defined by  $t_{VM\_del\_max}$ .

### Li-ion battery monitoring and balancing IC



### 7 Measurement control (MC)

If the long-running mode is selected for PCVM and/or BVM by writing the corresponding bits in the measurement control register, the IC measures eight times in a row using the 14-bit measurement mode. If the long-running mode is selected for SCVM by writing the corresponding bits in the measurement control register, the IC performs eight times several 11-bit measurements while the measurement time  $t_{VM}$  of a 14-bit measurement. After the long running measurements are finished the PCVM result register contains the average of all 14-bit measurements while the SCVM result register contains the average value of all 11-bit measurements.

Each of those measurements starts automatically after the time  $t_{restart}$ , for a total measurement time  $t_{VM}$  LR equals  $t_{VM}$  LR = 8 \*  $t_{restart}$ .

The time  $t_{restart}$  is defined by the configurable 6-bitfield of the operation mode register with a resolution of  $t_{\text{restart LSB}}$  within the range of  $t_{\text{restart\_range}}$ .

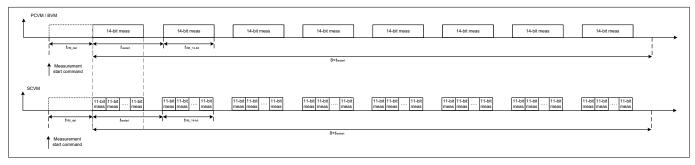


Figure 6 Voltage measurement long-running mode

#### 7.2 **Electrical characteristics measurement control (MC)**

#### Table 8 **Electrical characteristics**

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	5	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
MC PCVM, BAVM, AVM and BVM ADC sampling frequency	f <sub>s_ADC</sub>	13.4 4	14	14.5 6	MHz	1)	PRQ-600
MC PCVM, SCVM, BAVM and BVM propagation delay within IC	t <sub>VM_prop</sub>	2.75 µs - 1/ BR <sub>GP</sub>	-	3.5 µs - 1/ BR <sub>GP</sub>	S	Time between completion of a received measurement start command and the actual start of the measurement delay time t <sub>VM_del</sub> .	PRQ-592
MC PCVM, SCVM, BAVM and BVM start delay timer resolution	t <sub>VM_del_LSB</sub>	35.1	36.6	38.1	μs	1)	PRQ-593

### Li-ion battery monitoring and balancing IC



# 7 Measurement control (MC)

### Table 8 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.	1		Number
MC PCVM, SCVM, BAVM and BVM start delay timer maximum interval	t <sub>VM_del_max</sub>	1.09	1.13	1.18	ms	1)	PRQ-594
MC Voltage measuremen t time	t <sub>VM</sub>	-	2 <sup>m</sup> / f s_ADC	-	S	<ol> <li>m bits: 10 ≤ m ≤ 16</li> <li>Mode: CVM_MODE; BVM_MODE</li> <li>Except for long-running mode</li> </ol>	PRQ-602
Long-running	mode						
MC long- running mode restart time - 1	t <sub>restart_1</sub>	1.13	1.17	1.22	ms	For LR_TIME = 00 <sub>H</sub>	PRQ-1919
MC long- running mode restart time - 2	t <sub>restart_2</sub>	1.20	1.25	1.3	ms	For LR_TIME = 01 <sub>H</sub>	PRQ-1920
MC long- running mode restart resolution	t <sub>restart_LSB</sub>	100. 1	104. 1	108. 5	μs	For LR_TIME > 01 <sub>H</sub>	PRQ-1297
MC long- running restart range	t <sub>restart_rang</sub>	1.13	_	8.03	ms	_	PRQ-1312
Full scale ran	ges						
MC PCVM, SCVM and comparator full-scale range	FSR <sub>PCVM</sub> FSR <sub>SCVM</sub> FSR <sub>Comp</sub>	0	_	5	V	1)	PRQ-623
MC BVM full- scale range	FSR <sub>BVM</sub>	4.75	_	60	V	Measured at $V_{U9P}$ - $V_{GND}$	PRQ-1924
MC BAVM full- scale range (table continu	FSR <sub>BAVM</sub>	-2	_	2	V	_	PRQ-1387

### Li-ion battery monitoring and balancing IC



# 7 Measurement control (MC)

### Table 8 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
MC AVM and TMP full- scale range	FSR <sub>AVM</sub> FSR <sub>TMP</sub>	0	-	2	V	1)	PRQ-792
Measuremen	t resolution	)		•	•		
MC PCVM resolution	V <sub>PCVM_LSB</sub>	_	FSR <sub>P</sub> cvm/ 2 <sup>m</sup>	_	V	1) m bits: 10 ≤ m ≤ 16	PRQ-599
MC SCVM resolution	V <sub>SCVM_LSB</sub>	_	FSR <sub>S</sub> CVM / 2 <sup>11</sup>	_	V	1)	PRQ-624
MC BVM resolution	V <sub>BVM_LSB</sub>	_	FSR <sub>B</sub> <sub>VM</sub> / 2 <sup>m</sup>	_	V	1) m bits: 10 ≤ m ≤ 16	PRQ-667
MC BAVM resolution	V <sub>BAVM_LSB</sub>	_	FSR <sub>B</sub> AVM/2	_	V	1) m bits: 10 ≤ m ≤ 16	PRQ-1388
MC AVM resolution	V <sub>AVM_LSB</sub>	_	FSR <sub>A</sub> VM/2 <sup>1</sup>	_	V	1)	PRQ-682

<sup>1)</sup> Not subject to production test; verified by design or characterization.

### Li-ion battery monitoring and balancing IC



8 Primary cell voltage measurement (PCVM)

# 8 Primary cell voltage measurement (PCVM)

### 8.1 Functional description

The primary cell voltage measurement (PCVM) unit of the IC can measure each cell voltage individually and simultaneously using the Un pins. The measured voltage is defined as  $V_{PCVM} = (V_{Un+1} - V_{Un})$  ( $0 \le n \le 8$ ) and is measured with the defined accuracy  $PCVM_{FRR}$  and a relative accuracy of  $PCVM_{FRR}$  rel.

The primary cell voltage measurement is initiated by setting the PCVM\_START bitfield in the MEAS\_CTRL register. The primary cell voltage is calculated using:  $V_{PCVM}[V] = (FSR_{PCVM} / 2^{16}) \times RESULT[LSB16]$ 

The measurement is triggered by a host controller command synchronously for all cells connected to the IC. These conditions apply:

- The maximum start measurement propagation delay is  $t_{\text{VM prop.}}$
- The maximum PCVM time deviation between channels within one IC is  $Dev_{PCVM\_IC}$ .
- The maximum PCVM time deviation across all ICs in a chain is Dev<sub>PCVM chain</sub>.
- The start of the measurement is delayed by the configurable time  $t_{VM\_del}$ .
- The maximum iso UART propagation delay is  $t_{isoU-prop-del}$ .

The number of activated cells can be configured in the PART\_CONFIG register. With the register minimum value  $0000_{\rm H}$  no cell is activated and with maximum value  $0FF8_{\rm H}$  all 9 cells are activated.

# 8.2 Electrical characteristics primary cell voltage measurement (PCVM)

#### Table 9 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	5	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Cell sense inp	outs						
PCVM differential input current Un	I <sub>Un_PCVM</sub>	18	25	32	μΑ	<ol> <li>During PCVM</li> <li>V<sub>PCVM</sub> = 5 V</li> <li>This differential current flows into Un+1 and has the opposite direction on Un for the channels (0 ≤ n ≤ 9)</li> <li>The typical average value I<sub>Un_PCVM</sub> : V<sub>PCVM</sub> / 200 kΩ</li> </ol>	PRQ-1879
Input leakage current Un	I <sub>Un_leak</sub>	-0.6	_	0.6	μА	<ol> <li>0 ≤ n ≤ 9</li> <li>In sleep mode and idle mode</li> <li>V<sub>Un</sub> ≤ 5.5 V</li> </ol>	PRQ-1895

### Li-ion battery monitoring and balancing IC



# 8 Primary cell voltage measurement (PCVM)

### Table 9 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	5	Unit	Note or condition	P- Number
		Min.	Тур.	Мах.			
Synchronizat	ion timing	1	•	1	1		
Maximum PCVM time deviation between channels within IC	Dev <sub>PCVM_IC</sub>	-0.5	-	+0.5	%	Deviation between $t_{VM}$ .	PRQ-596
Maximum PCVM time deviation across ICs	Dev <sub>PCVM_ch</sub>	-4	_	4	%	1)	PRQ-597
Primary cell v	oltage mea	surem	ent				
PCVM relative accuracy initial - RT	PCVM <sub>ERR_i</sub> nit	-0.8	-	0.8	mV	Relative accuracy over all devices against each other within the given conditions:  1. 16-bit mode 2. $(V_{Un+1} - V_{Un}) = 4.3 \text{ V}$ 3. $T_i = 25 ^{\circ}\text{C}$	PRQ-1880
PCVM relative accuracy	PCVM <sub>ERR_r</sub> el	-1	-	1	mV	Relative accuracy over all devices against each other within the given conditions:  1. 16-bit mode  2. $\Delta(V_{Un+1} - V_{Un}) = 600 \text{ mV}$ within 2.5 V $\leq (V_{Un+1} - V_{Un}) \leq 4.3 \text{ V}$ 3. $\Delta T_j = 10 \text{ K}$ within $-40^{\circ}\text{C} \leq T_j \leq 70^{\circ}\text{C}$ 4. Over a period of $t_0$ and $t_{0+x}$ (x $\leq$ 12 hours) $t_0$	PRQ-1848
PCVM accuracy EoL - 1	PCVM <sub>ERR_E</sub> OL_1	-1.1	_	1.1	mV	5) 3) 6) <b>1.</b> $2.5 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 3.6 \text{ V}$ <b>2.</b> $T_j = 25^{\circ}\text{C}$	PRQ-1896
PCVM accuracy EoL - 2	PCVM <sub>ERR_E</sub> OL_2	-1.2	-	1.2	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> 3.6 V < $(V_{Un+1} - V_{Un}) \le 4.3 \text{ V}$ <b>3.</b> $T_j = 25^{\circ}\text{C}$	PRQ-1897
PCVM accuracy EoL - 3	PCVM <sub>ERR_E</sub> OL_3	-2.0	-	2.0	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> $1 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 3.6 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 50^{\circ}\text{C}$	PRQ-1898

### Li-ion battery monitoring and balancing IC



### 8 Primary cell voltage measurement (PCVM)

### Table 9 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Value	S	Unit No	Note or condition	P-
		Min.	Тур.	Max.			Number
PCVM accuracy EoL - 4	PCVM <sub>ERR_E</sub> OL_4	-2.1	-	2.1	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> 3.6 V < $(V_{Un+1} - V_{Un}) \le 4.3 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 50^{\circ}\text{C}$	PRQ-1899
PCVM accuracy EoL - 5	PCVM <sub>ERR_E</sub> OL_5	-2.6	_	2.6	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> $1 \lor (V_{Un+1} - V_{Un}) \le 3.6 \lor$ <b>3.</b> $-40 \degree C \le T_j \le 150 \degree C$	PRQ-1900
PCVM accuracy EoL - 6	PCVM <sub>ERR_E</sub> OL_6	-2.8	-	2.8	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> 3.6 V < $(V_{Un+1} - V_{Un}) \le 4.3 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1901
PCVM accuracy EoL - 7	PCVM <sub>ERR_E</sub> OL_7	-2.6	-	2.6	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> $0.05 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 1 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1902
PCVM accuracy EoL - 8	PCVM <sub>ERR_E</sub> OL_8	-3.5	_	3.5	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> 4.3 V < $(V_{Un+1} - V_{Un}) \le 4.8 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1903
PCVM accuracy EoL - 9	PCVM <sub>ERR_E</sub> OL_9	-2.6	-	2.6	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> $1 \lor < (V_{Un+1} - V_{Un}) \le 3.6 \lor$ <b>3.</b> $-40 \degree C \le T_j \le 70 \degree C$	PRQ-1904
PCVM accuracy EoL - 10	PCVM <sub>ERR_E</sub> OL_10	-2.8	_	2.8	mV	5) 3) 6) <b>1.</b> 16-bit mode <b>2.</b> 3.6 V < $(V_{Un+1} - V_{Un}) \le 4.3 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 70^{\circ}\text{C}$	PRQ-1905
PCVM accuracy EoL - 10-bit	PCVM <sub>ERR_E</sub> OL_10bit	-15	_	15	mV	3) 6) <b>1.</b> 10-bit mode <b>2.</b> $0.05 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 4.8 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1881

<sup>1)</sup> Not subject to production test; verified by design or characterization.

Datasheet

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<sup>2)</sup> Initial accuracy verified by Infineon backend.

<sup>3)</sup> With 9 cells attached and activated

Test condition: The IC is pre assembled on a PCB. A PCVM is started at any time  $t_0$  within the device lifetime. The IC is in sleep mode between  $t_0$  and  $t_{0+x}$  and RR\_ERR\_CNT.RR\_SLEEP\_CNT bitfield is  $000_{\rm H}$ .

<sup>5)</sup> Lower resolution has additional quantization error e.g. additional  $PCVM_{ERR EOL} \pm 2 LSB[m]$ ; m bits:  $14 \le m \le 15$ 

# Li-ion battery monitoring and balancing IC



# 8 Primary cell voltage measurement (PCVM)

Please contact Infineon for more details for other ADC resolutions.

6) End-of-Life (EoL) accuracy; according to AEC-Q100 Grade 1 Rev. H automotive qualification

### Li-ion battery monitoring and balancing IC



9 Secondary cell voltage measurement (SCVM)

# 9 Secondary cell voltage measurement (SCVM)

### 9.1 Functional description

The device includes a secondary cell voltage measurement (SCVM) unit. The measured voltage  $V_{SCVM} = (V_{Gn} - V_{Un})$  (0  $\leq$  n  $\leq$  8) is measured with the accuracy  $SCVM_{ERR\_EOL}$  and a resolution of  $V_{SCVM\_LSB}$ .

The secondary cell voltage measurement is initiated by setting the SCVM\_START bitfield in the MEAS\_CTRL register. The secondary cell voltage is calculated using:  $V_{\text{SCVM}}[V] = (FSR_{\text{SCVM}} / 2^{11}) \times \text{RESULT}[\text{LSB11}]$ 

The SCVM unit can measure the voltage of at least one cell simultaneously with the primary cell voltage measurement within  $t_{\rm VM\_prop}$ . At least one cell must be enabled in the SCVM configuration register. The corresponding cells for SCVM must also be activated in the PART\_CONFIG register.

Note: A binary search algorithm follows the highest and the lowest cell voltage of all cells enabled in the SCVM\_CONFIG register for each sample. Within the sampling time  $1/f_{s\_SCVM\_ADC}$  both voltages are sampled once. The SCVM averages all samples of the lowest and all samples of the highest voltage over the entire measurement time.

A 2-bit update counter in each SCVM register, SCVM lowest cell voltage and SCVM highest cell voltage, indicates the availability of a new secondary cell voltage measurement.

After the measurement time, the SCVM needs additional time  $t_{\rm SCVM\_ave}$  to calculate the average results. After  $t_{\rm SCVM\_ave}$ , the value of the highest voltage measured by the SCVM is stored in the SCVM highest cell voltage register. The lowest voltage is stored in SCVM lowest cell voltage register, respectively.

Note: If a single cell is measured, then calculate the average of the two results registers to improve filtering.

# 9.2 Electrical characteristics secondary cell voltage measurement (SCVM)

#### Table 10 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Cell sensing in	nputs						
SCVM differential input current Gn	I <sub>Gn_SCVM</sub>	_	7	10	μΑ	<ol> <li>Average during SCVM</li> <li>V<sub>SCVM</sub> = 5 V</li> <li>This differential current flows into Gn and has the opposite direction on Un for channels 0 ≤ n ≤ 8</li> </ol>	PRQ-1883
Input leakage current Gn	I <sub>Gn_leak</sub>	-1.0	_	1.0	μА	<ol> <li>0 ≤ n ≤ 8</li> <li>In sleep mode and idle mode</li> <li>V<sub>Gn</sub> ≤ 5.5 V</li> </ol>	PRQ-1884
Synchronizat	ion timing						
SCVM to PCVM time deviation	Dev <sub>SCVM_PC</sub>	-0.5	_	+0.5	%	Within one IC, the maximum deviation between SCVM (11-bit) time and PCVM (11-bit) time.	PRQ-622

### Li-ion battery monitoring and balancing IC



### 9 Secondary cell voltage measurement (SCVM)

### Table 10 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
SCVM data averaging time	$t_{\sf SCVM\_ave}$	286	298	311	μs		PRQ-1390
Secondary ce	ll voltage m	easure	ement				
SCVM ADC sampling frequency	f <sub>s_SCVM_ADC</sub>	_	f <sub>s_AD</sub> c / 64	_	MHz	2)	PRQ-625
SCVM accuracy EoL - limited range	SCVM <sub>ERR_E</sub> OL_1	-19	-	19	mV	3) <b>1.</b> $2.7 \text{ V} \le (V_{Gn} - V_{Un}) \le 4.3 \text{ V}$ <b>2.</b> $-40^{\circ}\text{C} \le T_{j} \le 50^{\circ}\text{C}$	PRQ-626
SCVM accuracy EoL	SCVM <sub>ERR_E</sub> OL_2	-28	-	28	mV	3) <b>1.</b> $1 \text{ V} \le (V_{\text{Gn}} - V_{\text{Un}}) \le 4.8 \text{ V}$ <b>2.</b> $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-627
Maximum deviation between PCVM and SCVM	Δ PCVM_vs_SCV M	-25	-	25	mV	$1 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 4.8 \text{ V}$	PRQ-1305
Analog under	voltage and	overv	oltage	comp	arators		'
Comparator resolution	FSRV <sub>Comp</sub> _ LSB	_	FSR <sub>C</sub> omp / 2 <sup>10</sup>	_	V	2)	PRQ-629
Comparator accuracy - limited range	COMP <sub>ERR_1</sub>	-30	-	30	mV	<b>1.</b> $(V_{Gn} - V_{Un}) = 3.6 \text{ V}$ <b>2.</b> $-40^{\circ}\text{C} \le T_{j} \le 25^{\circ}\text{C}$	PRQ-1300
Comparator accuracy	COMP <sub>ERR_2</sub>	-50	_	50	mV	1. $1 \text{ V} < (V_{Gn} - V_{Un}) < 4.7 \text{ V}$ 2. $-40^{\circ}\text{C} < T_j < 150^{\circ}\text{C}$	PRQ-630
Comparator sampling frequency	$f_{COMP}$	1	_	_	MHz	2)	PRQ-632
Comparator checking time	$t_{\rm comp}$	_	2 <sup>10</sup> / f <sub>s_AD</sub> c	_	μs	2)	PRQ-635

- 1) Not subject to production test; verified by design or characterization.
- 2) Not subject to production test; verified by design or characterization.
- 3) End-of-Life accuracy; according to AEC-Q100 Grade 1 Rev. H automotive qualification

### Li-ion battery monitoring and balancing IC



10 Block voltage measurement (BVM)

# 10 Block voltage measurement (BVM)

### 10.1 Functional description

The IC can measure the sum total voltage of all the cells connected to the device using separate pins, called block voltage. The block voltage  $V_{\rm BVM}$  = ( $V_{\rm U9P}$  -  $V_{\rm GND}$ ) is measured with the accuracy  $BVM_{\rm ERR\_EOL}$  and a configurable resolution of  $V_{\rm BVM\_LSB}$ .

The block voltage measurement is initiated by setting the BVM\_START bitfield in the MEAS\_CTRL register. The block voltage is calculated:  $V_{\text{BVM}}[V] = (FSR_{\text{BVM}} / 2^{16}) \times \text{RESULT\_BVM} [LSB16]$ 

# 10.2 Electrical characteristics block voltage measurement (BVM)

#### Table 11 Electrical characteristics

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40\,^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	nit Note or condition	P-
		Min.	Тур.	Max.			Number
Cell sense inp	outs						
BVM input current U9P	I <sub>U9P_BVM</sub>	-	280	400	μΑ	1) During BVM	PRQ-1886
Block voltage	measurem	ent					
Maximum BVM to PCVM time deviation within IC	Dev <sub>BVM_PCV</sub> M_IC	-0.5	-	+0.5	%	Deviation between BVM $t_{\rm VM}$ and PCVM $t_{\rm VM}$ with the same resolution setting.	PRQ-670
Maximum BVM time deviation across ICs	Dev <sub>BVM_cha</sub>	-4	-	4	%	Deviation between BVM $t_{\rm VM}$ over all ICs with the same resolution setting.	PRQ-671
BVM accuracy EoL - 1	BVM <sub>ERR_EO</sub>	-50	_	50	mV	3) <b>1.</b> 14-bit to 16-bit mode <b>2.</b> $4.75 \text{ V} \le V_{\text{BVM}} \le 38.7 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 70^{\circ}\text{C}$	PRQ-1915
BVM accuracy EoL - 2	BVM <sub>ERR_EO</sub>	-55	_	55	mV	3) <b>1.</b> 14-bit to 16-bit mode <b>2.</b> $4.75 \text{ V} \le V_{\text{BVM}} \le 45 \text{ V}$ <b>3.</b> $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1914
BVM accuracy EoL - 10 Bit	BVM <sub>ERR_10</sub> Bit	-250	-	110	mV	1) 3)  1. 10-bit mode  2. $4.75 \text{ V} \le V_{\text{BVM}} \le 45 \text{ V}$ 3. $-40^{\circ}\text{C} \le T_{\text{j}} \le 150^{\circ}\text{C}$	PRQ-1916

### Li-ion battery monitoring and balancing IC



### 10 Block voltage measurement (BVM)

#### Table 11 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_i = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
BVM versus sum of PCVM relative accuracy EoL	BVM <sub>ERR_vs_</sub> PCVM	BVM <sub>E</sub> RR_EO L_2_m in + 9 × PCV M <sub>ERR</sub> _EOL_ 6_min	-	BVM <sub>E</sub> RR_EO L_2_m ax + 9 x PCV M <sub>ERR</sub> _EOL_ 6_max		14-bit to 16-bit mode	PRQ-1917
Relative ADC error margin - sum of PCVM versus BVM EoL	ERR <sub>PCVM_B</sub> VM_10bit	-78	-	78	mV	<ol> <li>10-bit mode</li> <li>-40°C ≤ T<sub>j</sub> ≤ 150°C</li> <li>1 V ≤ (V<sub>Un+1</sub> - V<sub>Un</sub>) ≤ 4.8 V</li> <li>Plausibility check as part of the round robin scheme</li> </ol>	PRQ-1851

<sup>1)</sup> Not subject to production test; verified by design or characterization.

Not subject to production test; verified by design or characterization.

<sup>2)</sup> 3) End-of-Life accuracy; according to AEC-Q100 Grade 1 Rev. H automotive qualification

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11 Auxiliary voltage measurement (AVM)

# 11 Auxiliary voltage measurement (AVM)

### 11.1 Functional description

The IC also provides the possibility to measure other voltages, called auxiliary voltage measurement. The auxiliary voltage  $V_{\text{AVMz}} = (V_{\text{TMP}_z} - V_{\text{TMP}_G\text{ND}})$ ,  $(0 \le z \le 4)$  is measured with the accuracy  $AVM_{\text{ERR}_E\text{OL}}$  and a resolution of  $V_{\text{AVM}_L\text{SB}}$ .

The auxiliary voltage measurement is initiated by setting the AVM\_START bitfield in the MEAS\_CTRL register. The auxiliary voltage is calculated using:  $V_{\text{AVM}_Z}[V] = (FSR_{\text{AVM}} / 2^{10}) \times \text{RESULT}[LSB10]$ 

Additional to the unipolar AVM the device can be configured to measure a bipolar voltage applied on the TMP3 and TMP4 pins instead. The voltage  $V_{\text{BAVM}} = (V_{\text{TMP4}}, V_{\text{TMP3}})$  is measured with the accuracy  $BAVM_{\text{ERR\_EOL}}$  and a configurable resolution of  $V_{\text{BAVM LSB}}$ .

The BAVM measurement is enabled by setting the AVM\_CONFIG.AUX\_BIPOLAR bitfield, the resolution is set by the MEAS\_CTRL.BVM\_MODE and the measurement is triggered by the MEAS\_CTRL.BVM\_START bit. The BAVM measurement result is stored in the BVM result register.

The bipolar voltage is calculated using:  $V_{\text{BAVM}} = (\text{BVM.RESULT}[\text{signed LSB15}] \times 2 \text{ V}) / 2^{15}[\text{LSB15}]$ 

Note: Either BVM or BAVM can be performed synchronized to the PCVM/SCVM.

All external temperature measurement channels can be selected to be measured by the AVM function:

To measure an auxiliary voltage using a TMP channel, the temperature measurement function must be disabled in the temperature measurement configuration register. Since only one auxiliary voltage can be measured at a time, the configured auxiliary channels are measured sequentially.

### 11.2 Electrical characteristics auxiliary voltage measurement (AVM)

### Table 12 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit N	Note or condition	P-
		Min.	Тур.	Max.			Number
AVM accuracy EoL	AVM <sub>ERR_EO</sub>	-10	-	10	mV	1)  1. 10-bit mode  2. $0.1 \text{ V} \le V_{\text{AVMy}} \le 1.95 \text{ V}$ 3. $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-684
BAVM accuracy EoL	BAVM <sub>ERR_E</sub> OL	-3.3	_	3.3	mV	1)  1. 14-bit to 16-bit mode  2. $-2 \text{ V} \le V\text{TMP3}/4 \le 2 \text{ V}$ 3. $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1389
BAVM accuracy EoL - long- running mode	BAVM <sub>ERR_E</sub> OL_LR	BAV M <sub>ERR</sub> _EOL <sup>-</sup> 14.7	-	BAV M <sub>ERR</sub> _EOL + 14.7	mV	1. Long-running mode 2. $-2 \text{ V} \le V_{\text{TMP3/4}} \le 2 \text{ V}$ 3. $-40^{\circ}\text{C} \le T_{j} \le 150^{\circ}\text{C}$	PRQ-1829

<sup>1)</sup> End-of-Life accuracy; according to AEC-Q100 Grade 1 Rev. H automotive qualification



12 Temperature measurement unit (TMP)

# 12 Temperature measurement unit (TMP)

## 12.1 Functional description

The temperature measurement unit provides the possibility to measure up to five external temperature NTCs as well as two internal temperature sensors and provides the results in the corresponding temperature registers. A valid bit, which is cleared after readout, indicates a new measurement result in both cases.

The NTCs are measured with an accuracy of  $NTC_{ERR}$  whilst the internal sensor accuracy is defined by  $T_{ERR}$  int abs.

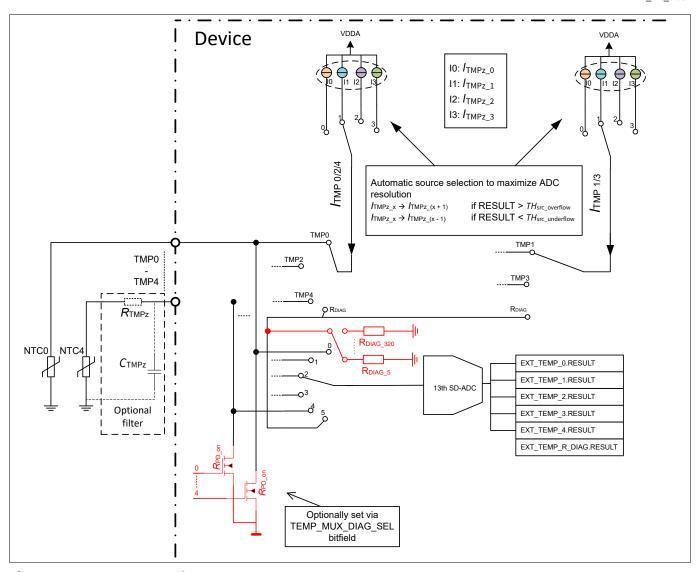


Figure 7 External temperature measurement

If not all provided measurement channels are needed, unused channels must be deactivated in the temperature configuration register.

Note: The TMP channels must be connected in consecutive order starting with TMP0. Deactivated channels can be used as AVM inputs.

The internal temperature measurement as well as the measurement of the selected NTC channels are triggered via the internal round robin. Within three round robin cycles all NTCs are updated.

Note: The first round robin after wake-up does not measure any NTC.

#### Li-ion battery monitoring and balancing IC

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#### 12 Temperature measurement unit (TMP)

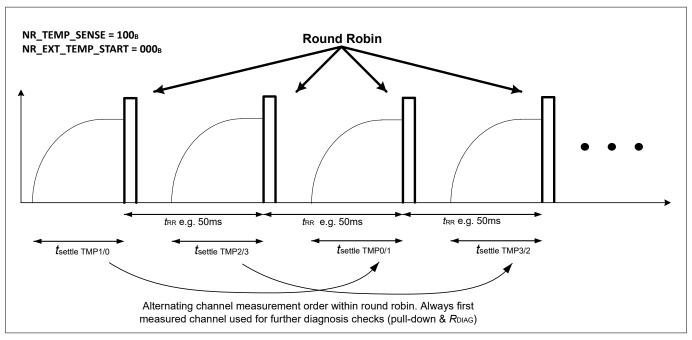


Figure 8 TMP triggering

To measure an external NTC, the device provides four selectable internal current sources  $I_{TMPz\_x}$  ( $0 \le z \le 4$ ,  $0 \le x \le 3$ ). The device automatically identifies which one of the four sources is the best one to use in the next round robin for each NTC channel individually by using the overflow and underflow thresholds  $TH_{Src\_overflow}$  and  $TH_{Src\_underflow}$ .

Current source  $I_{\mathsf{TMPz}\_1}$  is selected first. If, for example, an overflow is detected, the next lower source is selected. A valid result is available (or NTC short/open is detected) after maximum three round robin cycles per activated NTC channel.

Note: The source is activated prior to the measurement. The time is defined by  $t_{\text{settle}}$ .

For every TMP channel, a result register is available. The results register contains the following information:

- The result of the measurement.
- The used current source.
- The valid bit is set to indicate a new measurement. Reading the result clears the valid bit.
- Whether the pull-down of this channel was activated.
- Whether a pull-down error occurred.

The NTC resistor value is calculated by using the voltage measurement result and the selected current source.  $R_{\rm NTC}$  [ $\Omega$ ] = (EXT\_TEMP\_z.RESULT [LSB10] ×  $FSR_{\rm TMP}$  [V] ×  $4^{\rm EXT\_TEMP\_z.INTC}$ ) / ( $2^{10}$  × 320  $\mu$ A) -  $R_{\rm TMP}$ ; INTC = 0 to 3 (used current source).

To check if the temperature measurement unit works correctly the IC performs internal diagnostics checks as part of the round robin:

- 1. It measures an internal diagnostics resistor  $R_{\text{DIAG}}$  with the current source  $I_{\text{TMPz}_x}$  ( $0 \le x \le 3$ ,  $0 \le z \le 4$ ) used for TMPz.
- 2. It activates the pull down switch of the selected TMP channel after the measurement and it measures the channel again. The measured value is then compared with the expected value  $R_{\rm PD\_ON}$ . An open wire or increased resistance value can be detected and is indicated by setting the GEN\_DIAG.EXT\_T\_ERR (external temperature error).

Note: Only one TMP channel is checked per RR cycle (channel that was measured first during RR). The pull down resistor can be activated by setting the corresponding bits in the auxiliary voltage measurement configuration register

The device checks whether an overtemperature condition at the NTC exists by comparing the voltage measurement result against the external overtemperature threshold.

#### Li-ion battery monitoring and balancing IC



#### 12 Temperature measurement unit (TMP)

The 10-bit overtemperature threshold is configurable with a resolution of  $V_{\text{TMP\_LSB}}$  using the external overtemperature threshold bits of the temperature measurement configuration register TEMP\_CONF.EXT\_OT\_THR.

Note: In order to ensure the detection of an external overtemperature, the overtemperature threshold must be defined within the range of 250 to 800 (LSB10).

The device additionally checks if an overtemperature condition on at least one of the internal temperature sensors exists by comparing the measurement result against internal overtemperature threshold which is valid for both sensors.

The 10-bit overtemperature threshold is configurable with a resolution of  $T_{\text{int\_LSB}}$  using the internal overtemperature threshold bits of the internal temperature measurement configuration register INT\_OT\_WARN\_CONF.INT\_OT\_THR (recommended value:  $T_i = 150$ °C).

If the overtemperature threshold is reached, the device disables the balancing function and sets the internal overtemperature warning flag.

The junction temperature  $T_j$  can be calculated using the formula: Temperature [°C] =  $-T_{int\_LSB} \times INT\_TEMP\_x$ .RESULT + 547.3,  $(1 \le x \le 2)$ 

## 12.2 Electrical characteristics temperature measurement (TMP)

#### Table 13 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	S	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Internal temp	perature sen	sor	•		•		
TMP internal temperature resolution	$T_{int\_LSB}$	_	0.66 24	_	K	1)	PRQ-787
TMP internal temperature accuracy EoL absolute	$T_{ERR\_int\_abs}$	-10	_	10	°C	_	PRQ-788
External tem	perature ser	isors			•		
TMP measuremen t resolution	V <sub>TMP_LSB</sub>	_	FSR <sub>T</sub> MP/2	_	V	-	PRQ-1303
TMP measuremen t accuracy - 1	TMP <sub>ERR_1</sub>	-2	_	2	%	Accuracy of measured NTC resistance value in the range of 1.22 k $\Omega$ to 390 k $\Omega$	PRQ-789
TMP measuremen t accuracy - 2	TMP <sub>ERR_2</sub>	-4.2	-	4.2	%	Accuracy of measured NTC resistance value in the range of 610 $\Omega$ to 1.22 k $\Omega$	PRQ-790
TMP measuremen t accuracy - 3	TMP <sub>ERR_3</sub>	-6.2	_	6.2	%	Accuracy of measured NTC resistance value in the range of 400 $\Omega$ to 610 $\Omega$	PRQ-791

(table continues...)

## Li-ion battery monitoring and balancing IC



### 12 Temperature measurement unit (TMP)

### Table 13 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
TMP pull- down switch on-state resistance	R <sub>PD_on</sub>	_	_	400	Ω	_	PRQ-797
TMP source selection overflow threshold	TH <sub>src_overfl</sub> ow	_	1000	_	LSB10	1)	PRQ-803
TMP source selection underflow threshold	TH <sub>src_underf</sub>	-	200	_	LSB10	1)	PRQ-804
TMP current source activation before RR starts	t <sub>settle</sub>	38.4	40	41.8 + t <sub>vm</sub>	ms	$t_{\rm RR} > t_{\rm settle}$	PRQ-777
TMP measuremen t current source 3	I <sub>TMPz_3</sub>	4.5	5	5.5	μΑ	<ol> <li>0 ≤ z ≤ 4</li> <li>Within FSR<sub>TMP</sub></li> </ol>	PRQ-868
TMP measuremen t current source 2	I <sub>TMPz_2</sub>	19.0	20	21.1	μΑ	<ol> <li>0 ≤ z ≤ 4</li> <li>Within FSR<sub>TMP</sub></li> </ol>	PRQ-869
TMP measuremen t current source 1	I <sub>TMPz_1</sub>	75.9	80	84.1	μΑ	<ol> <li>0 ≤ z ≤ 4</li> <li>Within FSR<sub>TMP</sub></li> </ol>	PRQ-870
TMP measuremen t current source 0	I <sub>TMPz_0</sub>	304. 0	320	336. 0	μΑ	<ol> <li>0 ≤ z ≤ 4</li> <li>Within FSR<sub>TMP</sub></li> </ol>	PRQ-871
TMP internal diagnostics resistor source 0_320uA	R <sub>DIAG_320</sub>	3.82 5	5.1	6.37	kΩ	-	PRQ-799

(table continues...)

#### Li-ion battery monitoring and balancing IC



### 12 Temperature measurement unit (TMP)

#### Table 13 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values			Note or condition	P-
		Min.	Тур.	Мах.			Number
TMP internal diagnostics resistor source 1_80uA	R <sub>DIAG_80</sub>	8.4	11.2	14	kΩ	_	PRQ-800
TMP internal diagnostics resistor source 2_20uA	R <sub>DIAG_20</sub>	19.8 75	26.5	33.1 25	kΩ	-	PRQ-801
TMP internal diagnostics resistor source 3_5uA	R <sub>DIAG_5</sub>	46.5	62	77.5	kΩ	-	PRQ-802

<sup>1)</sup> Not subject to production test; verified by design or characterization.



13 Cell balancing (CB)

# 13 Cell balancing (CB)

# 13.1 Functional description

The IC supports balancing of each cell in the cell stack individually in any combination including all channels in parallel with a balancing current per cell of  $I_{BAL}$ .

Overview of balancing current for one cell:

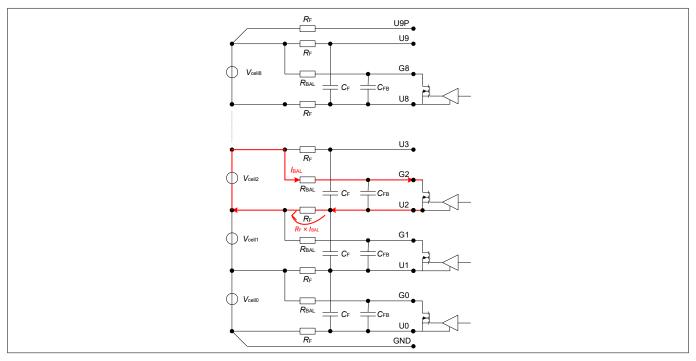


Figure 9 Passive balancing

To activate cell balancing, the respective bit in the balancing settings register can bet set for each cell individually.

If the PBOFF bit in the measurement control register is set, then the IC pauses balancing automatically. The balancing is paused for the duration of a PCVM/SCVM/BVM measurement ( $t_{\text{VM}} + t_{\text{VM\_del}}$ ) so that the cell voltage measurement is not corrupted by any ongoing balancing.

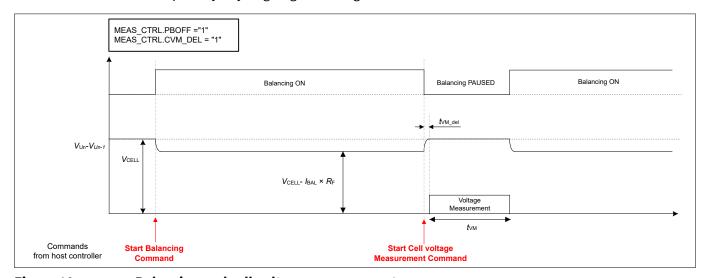


Figure 10 Balancing and cell voltage measurement

#### Li-ion battery monitoring and balancing IC



#### 13 Cell balancing (CB)

The IC can balance each cell for an individual period of time, without necessary periodic WDOG communication.

The individual time  $t_{BAL}$  is compared to the balancing counter.  $t_{BAL}$  is defined by  $t_{BAL}$  OFFn LSB with a maximum interval defined by  $t_{BAL\ OFFn\ max}$ . The balancing of each cell is active until the balancing counter reaches the cell individual threshold.

If the extended watchdog function is enabled and a write command to the communication watchdog register is performed, then the balancing timer counter starts. The device deactivates time goal balancing as soon as the counter reaches the individual threshold  $t_{\text{BAL}}$ .

The IC supports a PWM balancing function with the period of  $t_{RR}$  and a PWM step size of  $t_{BAL\ PWM\ LSB}$ . The function can be configured via the communication interfaces by the host controller. If balancing for one or more cells is activated, then the device activates the balancing switch during the on-time of the PWM and deactivates it during the off-time of the PWM. Other functions such as the voltage measurement and round robin task can overrule the PWM balancing function.

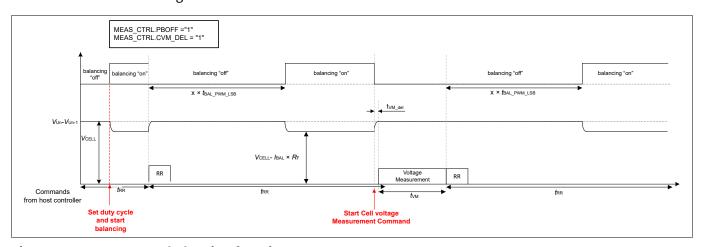


Figure 11 **PWM balancing function** 

Balancing is available in PCVM/SCVM long-running mode. If the PBOFF bit is set, then the device pauses cell balancing during the delay time of the measurement and during the measurement itself.

*Note:* Only if  $t_{vm}$  del +  $t_{vm}$  14bit <  $t_{restart}$ .

In addition to the internal passive balancing function, the IC also supports the use of an external passive balancing device. It is recommended to connect a PMOS logic level type device to the corresponding Gn pin as an external balancing device.



#### 13 Cell balancing (CB)

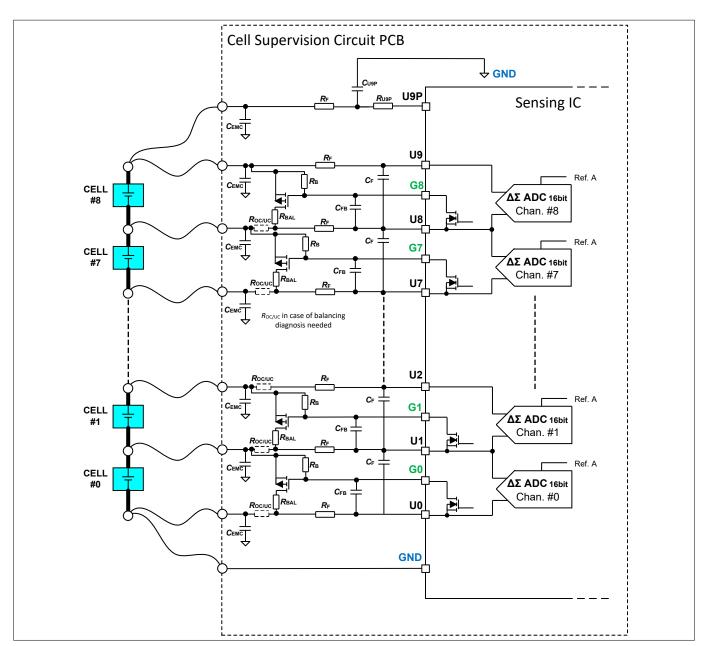


Figure 12 External balancing device

The IC supports overcurrent and undercurrent diagnostics for the external balancing device, using an additional resistor  $R_{\text{OC/UC}}$ .

Note: For the calculation of the overcurrent and undercurrent thresholds the voltage drop  $I_{\text{BAL}} \times R_{\text{OC/UC}}$  is used.

#### Li-ion battery monitoring and balancing IC



13 Cell balancing (CB)

# 13.2 Electrical characteristics cell balancing (CB)

# Table 14 Electrical characteristics

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	5	Unit	Note or condition	P-
		Min.	Тур.	Мах.			Number
CB balancing switch on- state resistance - 1	R <sub>BAL_on_1</sub>	1.5	2.6	5.0	Ω	1. $1 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 5 \text{ V}$ 2. $I_{\text{BAL}} \le 150 \text{ mA}$	PRQ-643
CB balancing switch on- state resistance - 2	R <sub>BAL_on_2</sub>	1.6	2.8	5.6	Ω	1. $1 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 5 \text{ V}$ 2. $150 \text{ mA} < I_{\text{BAL}} \le 200 \text{ mA}$	PRQ-1849
CB balancing current	I <sub>BAL</sub>	-	-	200	mA	$1 \text{ V} \le (V_{\text{Un}+1} - V_{\text{Un}}) \le 5 \text{ V}$	PRQ-645
Passive balan	cing timer						
CB Individual balancing time interval step	t <sub>BAL_OFFn_L</sub> SB	7.24	7.54	7.85	min	<ol> <li>1 ≤ n ≤ 9</li> <li>EXT_WD = 1</li> </ol>	PRQ-1889
CB Individual balancing timer maximum interval	t <sub>BAL_OFFn_</sub>	3.74	3.9	4.06	h	<ol> <li>1 ≤ n ≤ 9</li> <li>EXT_WD = 1, no WDOG timeout</li> <li>5-bit counter</li> </ol>	PRQ-1888
PWM balancir	ng						
CB balancing PWM step size	t <sub>BAL_PWM_L</sub> SB	_	t <sub>RR</sub> / 8	_	ms	1)	PRQ-1363



14 Cell diagnostics (CD)

# 14 Cell diagnostics (CD)

# 14.1 Functional description

The IC provides automatic open wire and open load detection for each wire connected to a cell. The device performs the detection by a voltage measurement while sinking the current  $I_{\text{OL\_DIAG}}$  into the balancing pin during a round robin cycle. It checks the odd channels in the first cycle and the even channels in the subsequent cycle.

If the delta voltage ( $(V_{Un+1} - V_{Un})$ ) before OL compared to ( $V_{Un+1} - V_{Un}$ ) during OL) is not between the minimum and maximum open load threshold, then a failure is detected. The open wire and open load-detection threshold can be configured with a resolution of  $OL_{thr\_LSB}$  until the maximum threshold of  $OL_{thr\_max}$  is reached using the cell voltage thresholds register.

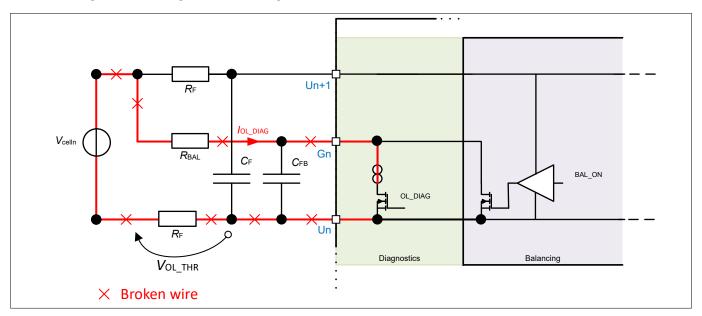


Figure 13 Open wire and open load diagnostics detection schematic

If the device detects an open wire or open load, then it indicates it in the corresponding bitfield of the diagnostics open load register as well as in the open load error bit of the general diagnostic register.

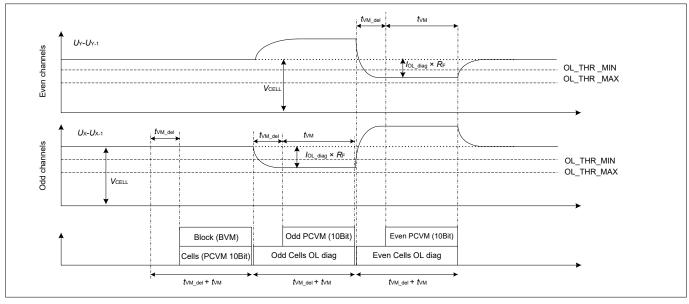


Figure 14 Open wire and open load diagnostics detection process

#### Li-ion battery monitoring and balancing IC



#### 14 Cell diagnostics (CD)

For OL\_THR\_MIN=0, no OL error is detected if the cell voltage is not decreased during activated OL current. For OL\_THR\_MAX=0, no OL error is detected if the cell voltage is decreased more than the value in the OL\_THR\_MAX register.

As part of the round robin the device performs a balancing overcurrent and an undercurrent check for each cell for which the balancing function is active. The overcurrent threshold  $OC_{thr}$  and the undercurrent threshold  $UC_{thr}$  is configurable with a resolution of  $CD_{thr\_LSB}$  until the maximum threshold of  $OC_{thr\_max}$  or  $UC_{thr\_max}$  respectively is reached using the balancing current threshold register.

If the device detects an balancing overcurrent or balancing undercurrent error, then it deactivates balancing. It reports error details in the BAL\_DIAG\_OC/BAL\_DIAG\_UC result register and summarized in the GEN\_DIAG.BAL\_ERR\_OC/BAL\_ERR\_UC bitfields.

By setting the configuration bit OP\_MODE.I\_DIAG\_EN, the device discharges all configured channels with the diagnostics current  $I_{\text{OL-DIAG}}$  regardless of the BAL\_SETTINGS register and independent of round robin.

### 14.2 Electrical characteristics cell diagnostics (CD)

#### Table 15 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	s	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Open load			•		_		
CD sink current for open load detection	I <sub>OL_DIAG</sub>	10	15	18.3	mA	0.75 V < (V <sub>Gn</sub> - V <sub>Un</sub> ) < 5 V	PRQ-650
CD open load threshold resolution	OL <sub>thr_LSB</sub>	_	19.5	-	mV	1)	PRQ-652
CD open load threshold maximum value	OL <sub>thr_max</sub>	-	1.23	-	V	1)	PRQ-651
Overcurrent &	& undercur	rent					
CD balancing overcurrent or undercurrent error threshold resolution	CD <sub>thr_LSB</sub>	-	19.5	_	mV	1)	PRQ-655
CD maximum balancing overcurrent error threshold	un_max	-	4.98	-	V	1)  1. OC_thr = overcurrent threshold  2. $I_{OC\_thr} = OC\_THR[V]/R_F$	PRQ-653

(table continues...)

## Li-ion battery monitoring and balancing IC



# 14 Cell diagnostics (CD)

### Table 15 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
CD maximum balancing undercurrent error threshold	un_max	-	4.98	-	V	1)  1. UC_thr = undercurrent threshold  2. $I_{UC\_thr} = UC\_THR[V]/R_F$	PRQ-654
CD balancing overcurrent detection time	t <sub>BAL_OC_DET</sub>	-	-	t <sub>RR</sub> _	ms	Equivalent to maximum round robin cycle time if the error counter is disabled (which is the default value, M_NR_ERR_BAL_OC = 1)	PRQ-646

<sup>1)</sup> Not subject to production test; verified by design or characterization.

#### Li-ion battery monitoring and balancing IC



15 General-purpose input/output (GPIO/PWM)

# 15 General-purpose input/output (GPIO/PWM)

# 15.1 Functional description

The device provides individual GPIOq/PWMp ( $0 \le q \le 1$ ,  $0 \le p \le 1$ ) pins which can be used for digital input or digital output.

After receiving a wake-up signal via iso UART, GPIOq can be used as GPIOs. A wake-up signal via UART sets the GPIOq pins to act as interface pins.

PWMp can be used as GPIO or be configured to act as PWM unit.

PWMp can be configured to act as PWM outputs using the GPIO register.

The period  $T_{PWM}$  and the duty cycle  $D_{PWM}$  can be configured with their respective resolution  $T_{PWM\_LSB}$  and  $D_{PWM\_LSB}$ .

### 15.2 Electrical characteristics general-purpose input/output (GPIO/PWM)

#### Table 16 Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note	or condition	P-
		Min.	Тур.	Мах.				Number
GPIO/PWM period resolution	T <sub>PWM_LSB</sub>	_	2	_	μs	Bitfie	eld with 5 bits.	PRQ-1338
GPIO/PWM duty cycle resolution	D <sub>PWM_LSB</sub>	_	3.57	_	%	1.	Bitfield with 5 bits. 100% DC = 11100 <sub>B</sub>	PRQ-1339
GPIO/PWM input "low" level	V <sub>GPIOq_low</sub> V <sub>PWMp_low</sub>	0	-	<i>V</i> <sub>VIO</sub> × 0.3	V	1.	0 ≤ q ≤ 1 0 ≤ p ≤ 1	PRQ-1393
GPIO/PWM input "high" level	$V_{ m GPIOq\_high}$ $V_{ m PWMp\_high}$	V <sub>VIO</sub> × 0.7	-	V <sub>VIO</sub>	V	1. 2.	$0 \le q \le 1$ $0 \le p \le 1$	PRQ-825
GPIO/PWM output "low" level	V <sub>GPIOq_low</sub> V <sub>PWMp_low</sub>	0	-	0.45	V	1. 2. 3.	$I_{GPIO} \le 5 \text{ mA}$ $0 \le q \le 1$ $0 \le p \le 1$	PRQ-826
GPIO/PWM output high level	V <sub>GPIOq_high</sub> V <sub>PWMp_high</sub>	V <sub>VIO</sub> - 0.45	_	V <sub>VIO</sub>	V	1. 2. 3.	$I_{GPIO} \ge -5 \text{ mA}$ $0 \le q \le 1$ $0 \le p \le 1$	PRQ-827
GPIO/PWM output current	I <sub>GPIOq</sub> I <sub>PWMp</sub>	-5	_	5	mA	1. 2. 3.	Current capability of GPIO/PWM output 0 ≤ q ≤ 1 0 ≤ p ≤ 1	PRQ-829

(table continues...)

#### Li-ion battery monitoring and balancing IC



15 General-purpose input/output (GPIO/PWM)

### Table 16 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Мах.			Number
External capacitance	C <sub>GPIOq</sub>	_	_	30	pF	1) <b>1.</b> 0 ≤ q ≤ 1	PRQ-830
on GPIOq/ PWMp	СРШМр					2. $0 \le p \le 1$	

<sup>1)</sup> Not subject to production test; verified by design or characterization.

# infineon

#### 16 Communication

### 16 Communication

### 16.1 Functional description

The device supports the following communication interfaces.

- 1. UART
- 2. iso UART

iso UART communications allows to stack multiple devices.

The device can be used in different configurations:

- Direct connection via UART, for low voltage applications
- Primary on bottom (PoB) communication with EMM function
- Primary on top (PoT) communication with EMM function
- Ring communication with EMM function

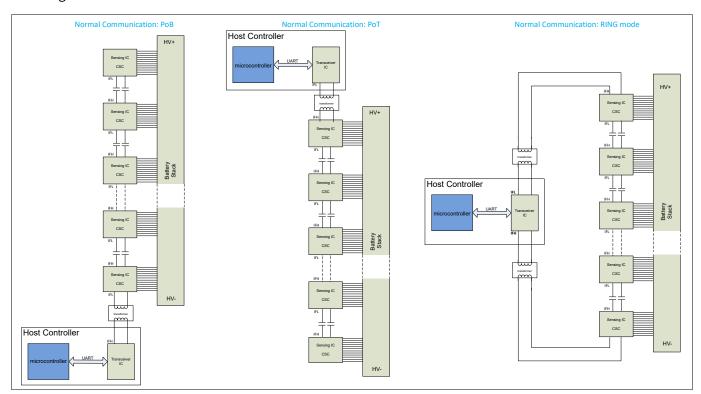


Figure 15 Communication configurations

The IC communication direction is determined during a wake-up cycle. The device configures the iso UART interface or the UART interface, which receives the wake-up pattern, as RX. The device configures the other interface as TX. To change the direction and consequently the pins, the device must be put to sleep and woken up again.

There is a reply delay  $t_{\text{reply\_delay}}$ , which determines the time between the last stop bit of the read/write command (incoming command from the primary) and the first falling edge of the reply frame from the secondary.

The device forwards a received message to the next device in the system. The time between receiving and forwarding the message depends upon the receiving interface:

- Receiving on UART and forwarding on iso UART:  $t_{\text{UART\_isoU\_del}}$
- Receiving on iso UART and forwarding on iso UART: t<sub>isoU prop del</sub>
- Receiving on iso UART and forwarding on UART:  $t_{\mathsf{UART\_isoU\_del}}$



#### 16 Communication

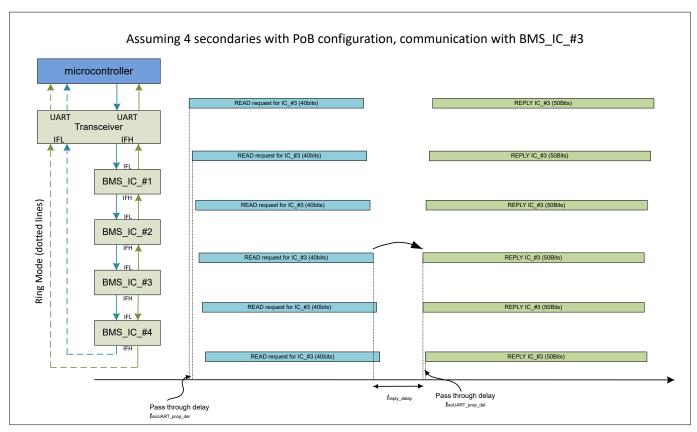


Figure 16 Communication propagation delays iso UART waveform specification

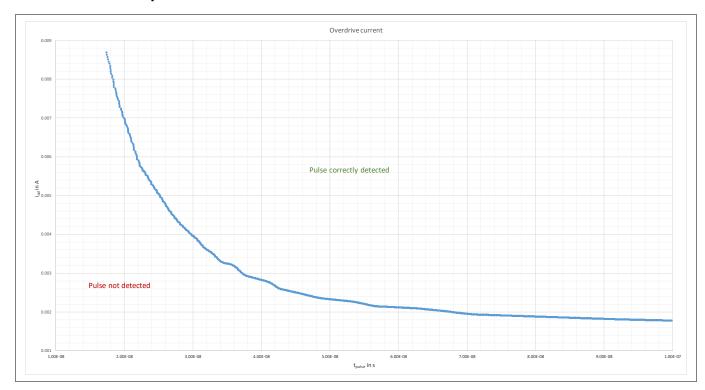


Figure 17 iso UART waveform specification

#### Li-ion battery monitoring and balancing IC

# infineon

#### 16 Communication

### 16.1.1 Register write modes

There are the following approaches for writing content into the device:

- Direct write: Writes a single register in a single device.
- Broadcast write: Writes a single register in all devices in the same stack with one write command.

With broadcast write, each device of the chain first writes data. On successful write it switches its RX and TX units to allow the reply frame to be transferred. The last device in the chain (final node) initiates the reply frame and the device switch their RX and TX units back to their initial state.

#### 16.1.2 Communication frames

UART and iso UART communication consists of sending or retrieving sets of frames. A frame consists of 8 bits preceded by a start bit and followed by a stop bit.

The following frames are available:

- Synchronization frame
- ID frame
- · Address frame
- Data frames
- CRC frame
- Reply frame

Note: Frames start with the most significant bit (MSB).

#### **Synchronization frame**

The communication is always initiated by sending a fixed synchronization frame.

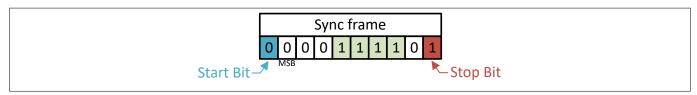


Figure 18 Synchronization frame

#### **ID frame**

The ID frame defines, which device receives the message. It also determines the type of command.



Figure 19 ID frame

#### Table 17 Bit assignment ID frame

ID frame bits	Function
W/R[7]	1: Write command
	0: Read command
ID[5:0]	000000: Default
	x: ID
	111111: Broadcast command

#### Li-ion battery monitoring and balancing IC



#### 16 Communication

Note: The ID  $00_H$  is only available after reset, before enumeration. The ID  $3F_H$  is exclusively used for broadcast commands.

#### **Address frame**

The address frame determines which register is affected by the read or write command.



Figure 20 **Address frame** 

#### **Data frame**

The data frame contains the sent or retrieved data.

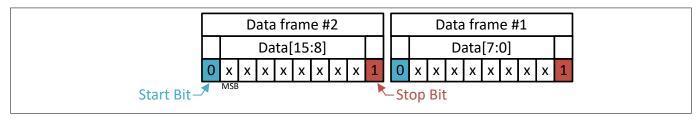


Figure 21 **Data frames** 

#### **CRC frame**

For read and write commands, an 8-bit CRC protection conforming to SAE J1850 for the entire message including the synchronization frame is calculated and appended to the frames.

8-bit polynomial:  $G(z) = z^8 + z^4 + z^3 + z^2 + 1$  (initial value =  $FF_H$ ; XOR value =  $FF_H$ )

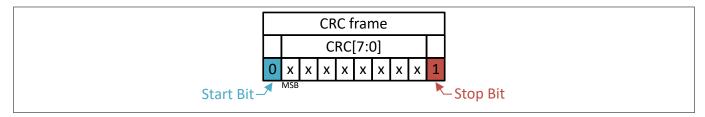


Figure 22 **CRC frame** 

Note: If the device encounters an invalid CRC, it neither accepts the message nor replies to it.

#### **Reply frame**

The device acknowledges a received write command with a reply frame. In case of a broadcast write command only the last device in the chain generates the reply frame.

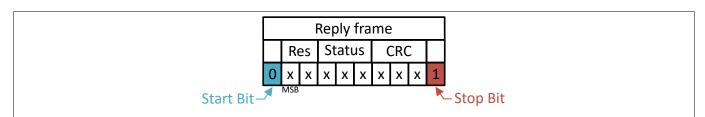


Figure 23 **Reply frame** 

The message reply frame is protected by a 3-bit CRC calculated as:  $G(z) = z^3 + z + 1$ .

#### Li-ion battery monitoring and balancing IC



#### 16 Communication

Table 18 Bit assignment reply frame

Reply-Frame	Function									
bit[7:6]	Res [1:0]	Reserved								
bit[5]	Status [2]	0: Write command successfully transmitted								
		1: CRC checked register error								
bit[4]	Status [1]	0: Register address for write command valid								
		1: Register address for write command invalid								
bit[3]	Status [0]	0: No fault in general diagnostics register								
		1: Fault in general diagnostics register								
bit[2:0]	CRC [2:0]	3-bit reply CRC								

#### **Register read modes** 16.1.3

There are the following approaches for reading content from the device:

- Direct read: Read a single register from a single IC.
- Broadcast read: Read a single register from all ICs in the same stack with one read command.
- Multi read: Read multiple registers from a single IC. The read command for multiple registers is configurable in the multi read register MULTI\_READ\_CFG and can read the following measurement results with one read command of the MULTI\_READ register:
  - **PCVM**
  - BVM
  - **SCVM**
  - External temperature measurement
  - Internal temperature measurement
  - R<sub>DIAG</sub> measurement

#### 16.2 **Electrical characteristics communication**

#### Table 19 **Electrical characteristics**

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Мах.			Number
GPIO/PWM pl	nysical layer	•	'	1			
UART to iso UART propagation delay	t <sub>UART_isoU_</sub> del	_	25	60	ns	Propagation delay from UART to iso UART	PRQ-828
GPIO bit rate	BR <sub>GPIO</sub>	0.97	2	2.1	Mbit/s	-	PRQ-831
UART broadcast read bus release time	t <sub>UART_rel_BR</sub>	_	_	15 × 1/ BR <sub>GP</sub>	S	Time to wait before sending a new command after end of broadcast read reply	PRQ-1909

#### (table continues...)

#### Li-ion battery monitoring and balancing IC



#### 16 Communication

#### Table 19 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Value	5	Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
UART read, write, broadcast write, multiread release time	t <sub>UART_rel</sub>	-	-	3 × 1/ BR <sub>GP</sub>	S	Time to wait before sending a new command after end of read/write/broadcast write/multiread reply	PRQ-1910
iso UART phy	sical layer						
iso UART current threshold "high"	I <sub>isoU_th_high</sub>	2.25	4.5	6.5	mA	(I <sub>IFx_H</sub> - I <sub>IFx_L</sub> ) / 2 I <sub>IFx_H</sub> : Current in the iso UART high pin I <sub>IFx_L</sub> : Current in the iso UART low pin	PRQ-832
iso UART current threshold "low"	I <sub>isoU_th_low</sub>	-6.5	-4.5	-2.25	mA	$(I_{IFx\_H} - I_{IFx\_L}) / 2$ $I_{IFx\_H}$ : Current in the iso UART high pin $I_{IFx\_L}$ : Current in the iso UART low pin	PRQ-833
iso UART propagation delay	$t_{isoU\_prop\_d}$ el	_	25	70	ns	Propagation delay from IFH to IFL and IFL to IFH	PRQ-834
iso UART overdrive current	I <sub>od</sub>	3	_	_	mA	with $t_{\text{pulse}} = 38 \text{ ns}$	PRQ-1370
Reply delay time	$t_{ m reply\_delay}$	0	1.7	3	μs	internal reply delay time of one IC	PRQ-837
iso UART bit rate	<i>BR</i> <sub>isoU</sub>	0.97	2	2.1	Mbit/s	-	PRQ-838
Series resistor value	R <sub>ser</sub>	37.0 5	39	40.9 5	Ω	2) 3)	PRQ-836
Series capacitor value	C <sub>ser</sub>	0.95	1	1.05	nF	2) 3)	PRQ-835
Transceiver Ron @100mA	R <sub>ON</sub>	19	22	27	Ω	-	PRQ-1845

<sup>1)</sup> Tested with standard external circuit ( $C_{ser}$ ,  $R_{ser}$ ).

Not subject to production test; verified by design or characterization.

<sup>2)</sup> 3) External RC network needs to be adjusted depending on the application constraints, for example cable length.



17 Round robin (RR)

#### Round robin (RR) **17**

#### 17.1 **Functional description**

The device automatically performs a round robin (RR) scheme, which triggers several measurements as well as internal diagnostics to check for possible faults independently of any communication commands.

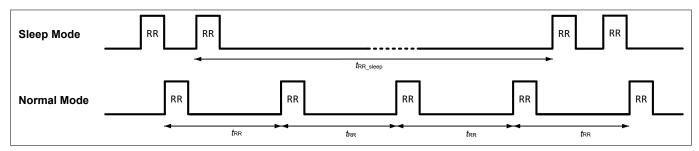
The setting of the partition configuration register determines, which cells are measured and diagnosed.

Note: To manually start a round robin cycle, use the RR CONFIG.RR SYNC bitfield and then perform a write command to WD CNT.

The automatic round robin diagnostic cycle is performed periodically every  $t_{RR}$ . The period is configurable from  $t_{RR min}$  to  $t_{RR max}$  with a resolution of  $t_{RR LSB}$ .

The duration of the actual diagnostic checks is defined by  $t_{\rm RR}$  duration. Note: The first round robin cycle is performed immediately after each IC wake-up. If the WD\_CNT command is missing or delayed for > t<sub>RR</sub>, then in RR SYNC mode the RR is performed automatically after  $t_{RR}$ .

The IC wakes up periodically from sleep mode to perform one RR cycle on a programmable periodical basis with an interval  $t_{\text{RR\_sleep\_min}}$  from  $t_{\text{RR\_sleep\_min}}$  to  $t_{\text{RR\_sleep\_max}}$  with a resolution of  $t_{\text{RR\_sleep\_LSB}}$ . If the number of NTCs is > 0, then two RR schemes are executed after wake-up before the IC returns to sleep mode.



Round robin diagnostics timing during sleep mode Figure 24

The following measurements are performed once during one round robin cycle in the following sequence:

- 1. Temperature measurements of both internal temperature sensors
- 2. ADC stress sensor compensation measurements and calculation
- 3. PCVM (10-bit) for all activated cells
- BVM (10-bit) 4.
- 5. NTC resistance measurement
- NTC diagnostic measurements

Note: To measure all connected NTCs up to three cycles might be needed. The result registers of PCVM and BVM are not updated.

During a round robin the following checks are performed subsequent to the corresponding measurements, if set active.

- 1. Internal overtemperature check
- The sum of all PCVMs is compared to the block voltage for a plausibility check 2.
- Cell voltage overvoltage and undervoltage check. If the voltage of a cell violates the programmed 3. threshold (identified either by the digital or the analog comparator)
- 4. Open load diagnostic for all voltage sensing and balancing pins
- 5. Balancing overcurrent and undercurrent check for each cell where the balancing function is active
- NTC overtemperature check 6.
- 7. NTC diagnostics checks

Each fault detected in a RR check increases the respective error counter by 1.

#### Li-ion battery monitoring and balancing IC



#### 17 Round robin (RR)

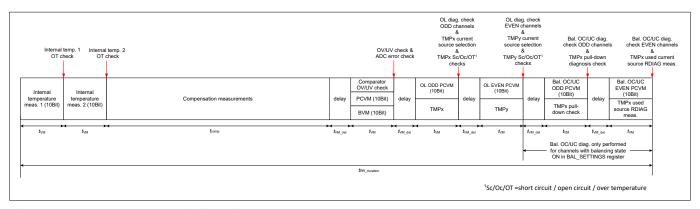


Figure 25 RR task timing diagram

During a round robin cycle, the connections on the activated TMPz channels are checked for open or short conditions. If it detects an open or short failure, then the corresponding fault bit in the external overtemperature warning register is set. Additionally, the external temperature error bit of the general diagnostics register is set. If the measured NTC value violates the corresponding thresholds, then an error flag is set.

 $NTC\_open_{thr} \leq EXT\_TEMP\_z.RESULT \leq NTC\_short_{thr}$ 

Clearing the external temperature error bit of the general diagnostics register resets the external overtemperature warning register.

Note: RR ERR CNT.NR EXT TEMP START bitfields setting and the current source range selection impacts the number of RRs needed to detect a failure condition.

If the device detects an error during a round robin cycle, the individual error counter is increased by one. If the error counter is greater than  $n_{\text{ERROR}}$ , the respective error bit is set. The counter limit  $n_{\text{ERROR}}$  (3-bit) is configurable and valid for all counters. It is possible to deactivate a specific error counter by setting a mask bit.

Note: Setting  $n_{\text{FRROR}}$  to 0, sets the error flag with the first detection of the failure condition.

The status of the diagnostics registers which have been updated during a round robin cycle can be read via a command. If a fault was detected, the information is latched and can be cleared via a clear command.

*Note: The following diagnostics registers are available:* 

- General diagnosis GEN\_DIAG
- Cell voltage supervision warning flag CELL\_UV
- Cell voltage supervision warning flag CELL\_OV
- External overtemperature warning flags EXT\_TEMP\_DIAG
- Diagnosis OPENLOAD DIAG OL
- Cell voltage supervision warning flags CELL\_UV\_DAC\_COMP
- Cell voltage supervision warning flags CELL\_OV\_DAC\_COMP
- Passive balancing diagnosis OVERCURRENT BAL\_DIAG\_OC (only if balancing function is active)
- Passive balancing diagnosis UNDERCURRENT BAL\_DIAG\_UC (only if balancing function is active)

The IC keeps the diagnostic results (except for BAL DIAG OC and BAL DIAG UC) in sleep mode, as long as the sleep mode supply is available on U9P pin. In sleep mode, the IC resets the passive balancing diagnostic registers for overcurrent BAL DIAG OC and undercurrent BAL DIAG UC.

After the 10-bit cell voltage measurement task in the round robin cycle, the measurement results are compared to configurable undervoltage and overvoltage thresholds. To configure the thresholds, the corresponding bits in the cell voltage thresholds registers can be set with a resolution of  $V_{\text{Comp. LSB}}$ .

The undervoltage detection is disabled in case of UV\_THR = 000<sub>H</sub>.

The overvoltage detection is disabled in case of OV\_THR = 3FF<sub>H</sub>.

The IC has an automatic overvoltage and undervoltage detection. The comparator monitors the  $V_{\rm Gn}$  - $V_{Un}$  voltage and sets the OV/UV bits in the registers CELL\_UV\_DAC\_COMP and CELL\_OV\_DAC\_COMP.

The delta sigma ADC monitors the  $(V_{Un+1} - V_{Un})$  voltage and sets the OV/UV bits in the registers.

#### Li-ion battery monitoring and balancing IC



#### 17 Round robin (RR)

In a round robin cycle, the balancing function is paused during overvoltage and undervoltage check.

If the RR\_SYNC bit is set, then the IC synchronizes the start of the round robin cycle to the watchdog command. If this bit is set, then the next round robin cycle is triggered every time the watchdog WD\_CNT is served. Additionally, the round robin counter is reset.

Note: Autonomous RR is active if  $t_{RR}$  expires before WD\_CNT command arrives. This mechanism can synchronize all devices in the chain as well as the round robin to other tasks.

After triggering a PCVM, SCVM, BVM, or AVM, the IC performs that measurement and terminates the round robin (case 3). The GEN\_DIAG.LOCK\_MEAS bit is set to 1 in this case and it is not possible to start a second manual measurement since RR cannot be skipped a second time, see cases 2, 3 and 4 in Figure. After the measurement is finished, the round robin task is restarted.

The round robin cycle has a lower priority than the triggered measurement.

Note: This is also true for a long running mode measurement.

#### Li-ion battery monitoring and balancing IC



#### 17 Round robin (RR)

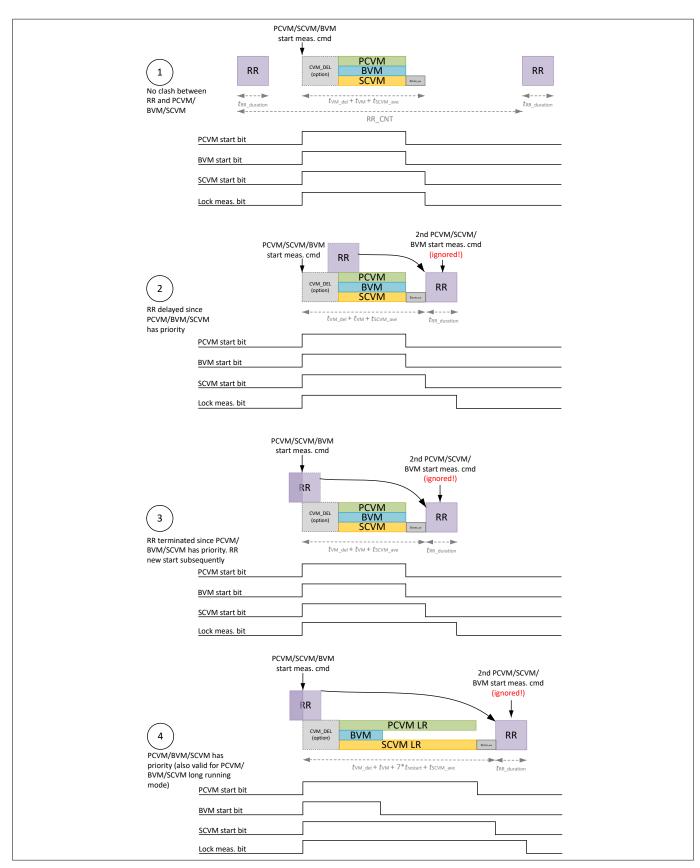


Figure 26 Prioritizing PCVM, SCVM, BVM, and AVM versus round robin

If a round robin is delayed by a manually triggered measurement, then the device synchronizes the subsequent RR scheme to start at the end of the measurement time  $t_{vm}$ .

#### Li-ion battery monitoring and balancing IC



#### 17 Round robin (RR)

Internal IC data, such as ADC trimming values is ECC protected and a register CRC check as well as an internal data check is executed with a fixed hardware cycle time  $t_{\rm CRC\_check}$  independent of the round robin scheme interval time  $t_{\rm RR}$ . The registers with the following addresses are CRC protected:  $01_{\rm H}$ ,  $02_{\rm H}$ ,  $03_{\rm H}$ ,  $04_{\rm H}$ ,  $05_{\rm H}$ ,  $08_{\rm H}$ ,  $09_{\rm H}$ ,  $04_{\rm H}$ ,  $15_{\rm H}$ ,  $17_{\rm H}$ ,  $36_{\rm H}$ ,  $38_{\rm H}$ .

Note: The register CRC error as well as the internal IC error do not have an error counter.

# 17.2 Electrical characteristics round robin (RR)

#### Table 20 Electrical characteristics

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Overvoltage a	and undervo	oltage	detect	ion			
OV/UV threshold resolution	V <sub>OVUV_LSB</sub>	_	FSR <sub>P</sub> CVM/ 2 <sup>10</sup>	_	mV	1)	PRQ-766
OV/UV threshold maximum value	V <sub>OVUV_max</sub>	0	_	FSR <sub>P</sub> CVM	V	1)	PRQ-767
Round robin	counter						
RR scheme duration	t <sub>RR_duration</sub>	_	_	1.2	ms	Only valid if the measurement delay time $t_{\rm VM\_del}$ is not higher than $t_{\rm VM\_del\_LSB}$ .	PRQ-774
RR interval step	t <sub>RR_LSB</sub>	1.12	1.17	1.22	ms	1)	PRQ-770
RR minimum interval	t <sub>RR_min</sub>	6.7	7.1	7.4	ms	1)	PRQ-768
RR maximum interval time	t <sub>RR_max</sub>	149	155. 7	163	ms	1) 7-bit counter	PRQ-769
RR sleep interval step	t <sub>RR_sleep_LS</sub>	13.6 4	15	16.6 7	sec	1)	PRQ-773
RR sleep maximum interval time	t <sub>RR_sleep_m</sub>	3.88	4.26	4.74	h	1) 10-bit counter	PRQ-771
Error counter	n <sub>ERROR</sub>	0	_	7	-	1) 3-bit counter	PRQ-776
CRC check cyclic interval	t <sub>CRC_check</sub>	47	49.1 5	52	ms	1)	PRQ-775

(table continues...)

## Li-ion battery monitoring and balancing IC



# 17 Round robin (RR)

### Table 20 (continued) Electrical characteristics

 $V_{VS} = V_{VS\_functional}$ ,  $T_j = -40$ °C to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
RR compensatio n measuremen t and calculation	t <sub>comp</sub>	385	405	425	μs	1)	PRQ-1392
ADC ERROR result (ΣPCVM versus BVM) comparison error threshold	ADC_ERR <sub>th</sub>	-	256	-	mV	_	PRQ-1304
NTC Open / sl	nort diagnos	tics			•		
NTC short threshold	NTC_short <sub>t</sub>	-	64	_	LSB10	Using $I_{TMPz_0}$ with $0 \le z \le 4$	PRQ-1306
NTC open threshold	NTC_open <sub>t</sub>	-	1023	-	LSB10	Using $I_{TMPz_3}$ with $0 \le z \le 4$	PRQ-1307

<sup>1)</sup> Not subject to production test; verified by design or characterization.

# infineon

18 Emergency mode (EMM) and ERR pin (ERR)

# 18 Emergency mode (EMM) and ERR pin (ERR)

# 18.1 Functional description

One of the following reactions of the IC to an error can be configured in the ERR pin/EMM mask register:

- Indicate the issue via a "high" level on the ERR pin.
- Send an emergency signal (EMM) via iso UART to each adjacent device in the chain.

The ERR pin is protected against short to GND.

The emergency signal is an alternating signal with the frequency  $f_{\rm EMM}$ . The EMM is received and sent via the iso UART communication interfaces.

The IC can detect and forward an EMM signal in sleep mode. The EMM signal is used for the IC wake-up. On detecting an EMM signal, the IC reproduces and forwards it to the opposite iso UART interface.

After the transmit process the IC returns to sleep mode.

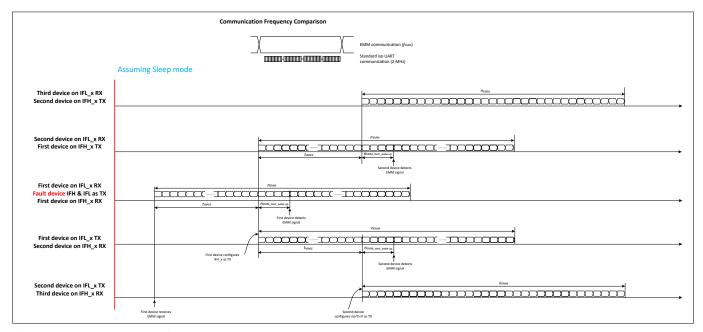


Figure 27 EMM in sleep mode process

With a chain in sleep mode, the EMM signal reaches the transceiver from both sides.



#### 18 Emergency mode (EMM) and ERR pin (ERR)

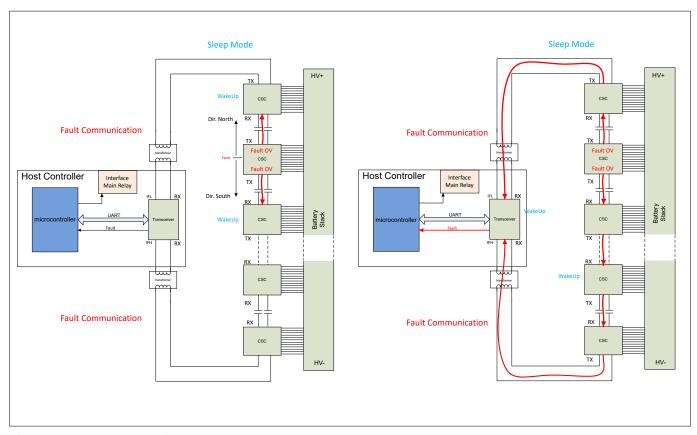


Figure 28 EMM in sleep mode path

In normal operation the communication mode (PoT or PoB) is already defined and the adjacent device shows either a TX or RX interface. In case of EMM, the contiguous device showing a TX interface will not forward the EMM signal. Therefore, the EMM signal follows the path that shows the RX interface back to the microcontroller.

#### 18 Emergency mode (EMM) and ERR pin (ERR)

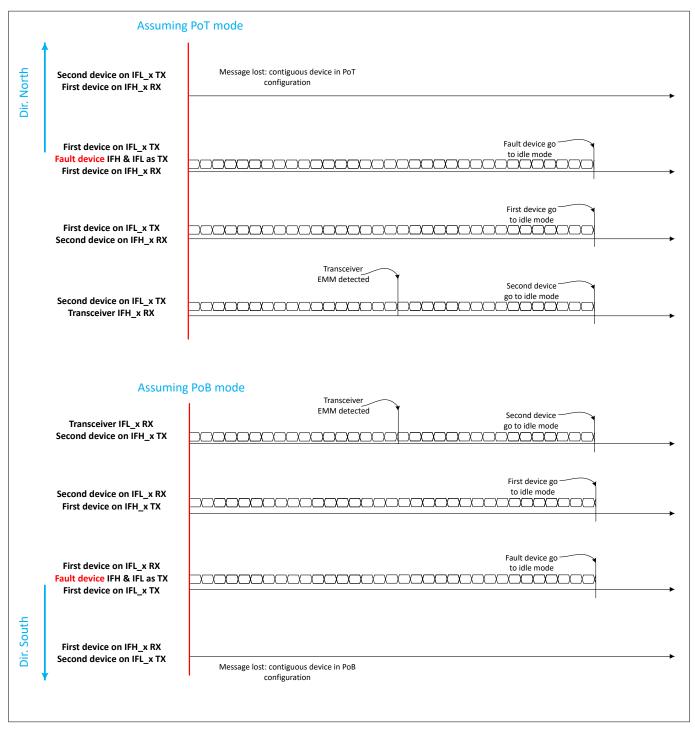


Figure 29 **EMM in normal mode process** 

#### Li-ion battery monitoring and balancing IC



#### 18 Emergency mode (EMM) and ERR pin (ERR)

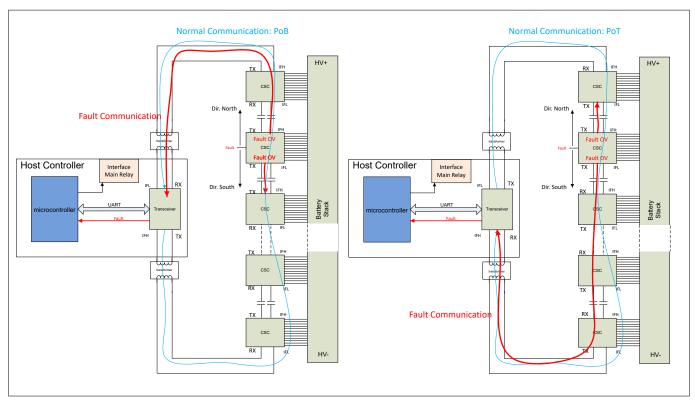


Figure 30 EMM in normal mode path

A device which sends the EMM signal transmits it for  $n_{\text{EMM}}$  periods. The number of periods the IC needs to detect and forward an EMM signal depends on the operation mode:

- **1.** Idle mode:  $n_{\text{EMM dect}}$
- 2. Straight after wake-up caused by EMM:  $n_{\text{EMM\_dect\_wake-up}}$

The IC's ERR pin default state is low and is pulled down using the external pull-down resistor  $R_{\text{ERR\_PD}}$ . If the device detects an error, then it switches the ERR pin to VS until the following actions are performed:

- The microcontroller clears the fault, which triggered the ERR signal.
- The IC enters sleep mode.

If a fault that activates the ERR pin is detected in round robin sleep, then the IC remains in normal mode until  $t_{\rm WD\_max}$  elapses.

The following faults can trigger the EMM mode or the ERR pin, depending on the configuration in the ERR pin / EMM mask register:

- Overvoltage or undervoltage of a cell
- External NTC resistance measurement fault
- Open load diagnostics error for any voltage sensing and balancing pin
- Balancing overcurrent and undercurrent error
- ADC cross-check error
- Internal overtemperature detected
- · Register CRC check fault detected
- Internal IC error

Setting the corresponding bits in the ERR pin and EMM mask register prevents faults from leading to an emergency signal (EMM) emission or to an ERR pin reaction.

#### Li-ion battery monitoring and balancing IC



18 Emergency mode (EMM) and ERR pin (ERR)

# 18.2 Electrical characteristics emergency mode (EMM) and ERR pin (ERR)

#### Table 21 Electrical characteristics

 $V_{\rm VS} = V_{\rm VS\_functional}$ ,  $T_{\rm j} = -40\,^{\circ}{\rm C}$  to +150°C, all voltages with respect to GND, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or condition	P-
		Min.	Тур.	Max.			Number
Emergency m	ode EMM		•	•	1		
EMM signal frequency	$f_{EMM}$	48	50	52	kHz	1)	PRQ-737
EMM number of periods to detect EMM signal - straight after wake-up	n <sub>EMM_dect_</sub> wake-up	4	-	4	period s	<ol> <li>Wake-up due to the EMM signal</li> <li>During forwarding of the wake-up signal</li> </ol>	PRQ-738
EMM number of periods to detect EMM signal - idle mode	n <sub>EMM_dect</sub>	16	-	16	period s	IC is in idle mode and not enumerated (ID = 0)	PRQ-740
Transmitted EMM signal periods	n <sub>EMM</sub>	32	-	32	period s	1)	PRQ-742
ERR pin funct	ion						•
ERR fault indication voltage	V <sub>ERR</sub>	V <sub>VS</sub> - 0.25	_	V <sub>VS</sub>	V	I <sub>ERR</sub> ≤ I <sub>ERR_max</sub>	PRQ-743
ERR input current	I <sub>ERR</sub>	-1	-	-	mA	Current capability of pin additionally to $R_{\text{ERR\_PD}}$ (= 100 k $\Omega$ ) current	PRQ-744
ERR pull- down resistor	R <sub>ERR_PD</sub>	75	100	-	kΩ	External pull down resistance	PRQ-745

<sup>1)</sup> Not subject to production test; verified by design or characterization.



19 Application information

# 19 Application information

# 19.1 External circuitry and components

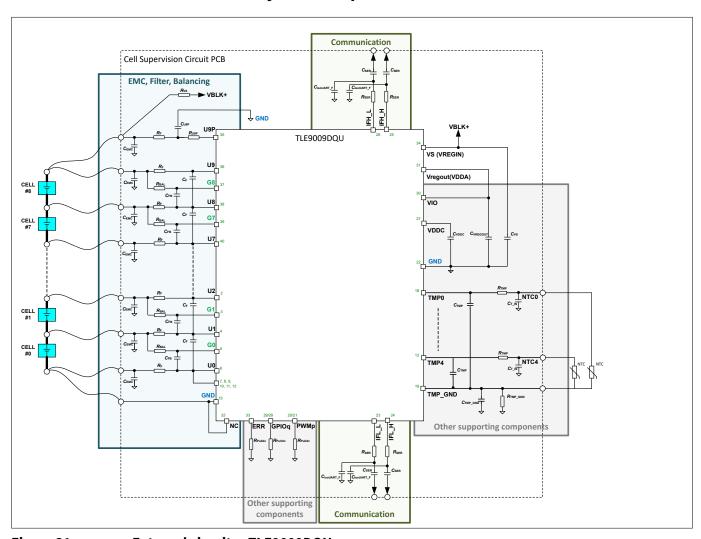


Figure 31 External circuitry TLE9009DQU

Table 22 External components

Name	Symbol	Тур.	Unit	Condition
External filter resistor RF	R <sub>F</sub>	10	Ω	Valid for pin U0 - U9
External filter resistor RU9P	R <sub>U9P</sub>	5.1	Ω	
External balancing resistor RBAL	R <sub>BAL</sub>	41	Ω	
External filter capacitor CF	C <sub>F</sub>	330	nF	
EMC network capacitor CEMC	C <sub>EMC</sub>	1	nF	

(table continues...)

# Li-ion battery monitoring and balancing IC



# 19 Application information

Table 22 (continued) External components

Name	Symbol	Тур.	Unit	Condition
Filter capacitor (Gn/Un) CFB	C <sub>FB</sub>	100	nF	
Buffer capacitor CVS	C <sub>VS</sub>	100	nF	
Filtering resistor RVS	R <sub>VS</sub>	5.1	Ω	
Buffer capacitor on U9P	C <sub>U9P</sub>	100	nF	
Buffer capacitor on VREGOUT	$C_{VREGOUT}$	100	nF	
Buffer capacitor on VIO	C <sub>VIO</sub>	100	nF	If VIO is connected to VREGOUT, then C <sub>VIO</sub> is omitted.
Buffer capacitor on VDDC	$C_{\text{VDDC}}$	330	nF	
Bypass capacitor on iso UART	C <sub>isoUART_F</sub>	220	pF	
Input capacitor on TMP	$C_{TMP}$	10	nF	
NTC filter resistor RTMP	R <sub>TMP</sub>	100	Ω	
NTC filter capacitor CT_IN	C <sub>T_IN</sub>	4.7	nF	
External wiring resistance	R <sub>WH_ch</sub>	0.2	Ω	



### 19 Application information

#### Typical application diagram 19.2

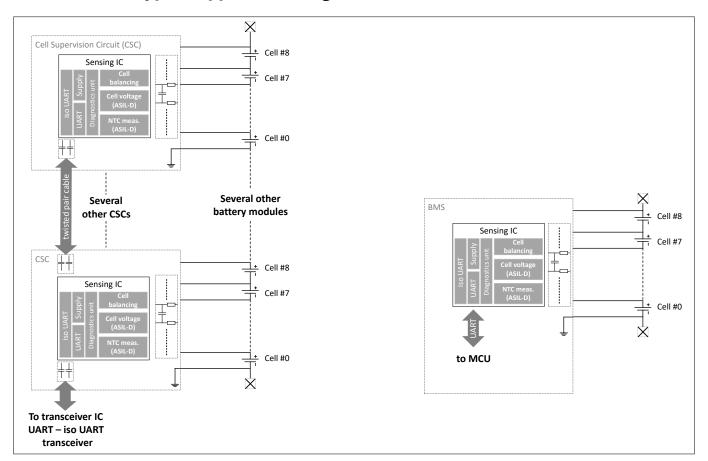


Figure 32 Typical application diagram

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#### 20 Package information

# 20 Package information

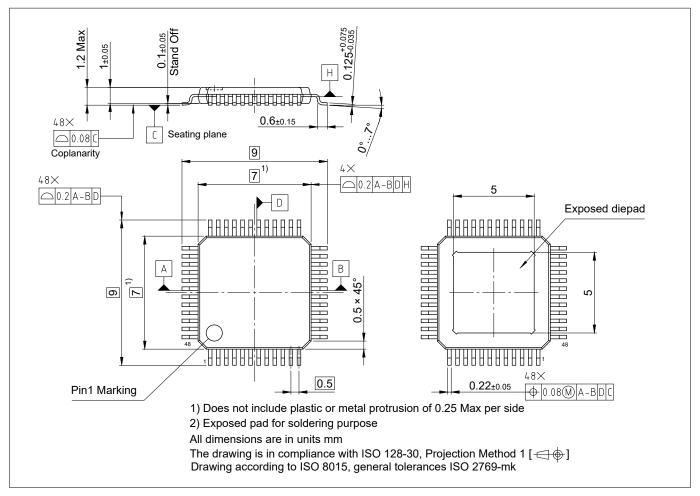


Figure 33 PG-TQFP-48

#### **Green Product (RoHS compliant)**

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a Green Product. Green Products are RoHS compliant (Pbfree finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

#### Information on alternative packages

Please visit www.infineon.com/packages.

# Li-ion battery monitoring and balancing IC



# 21 Revision history

# 21 Revision history

Revision	Date	Changes
1.0	2024-09-15	Datasheet release

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